

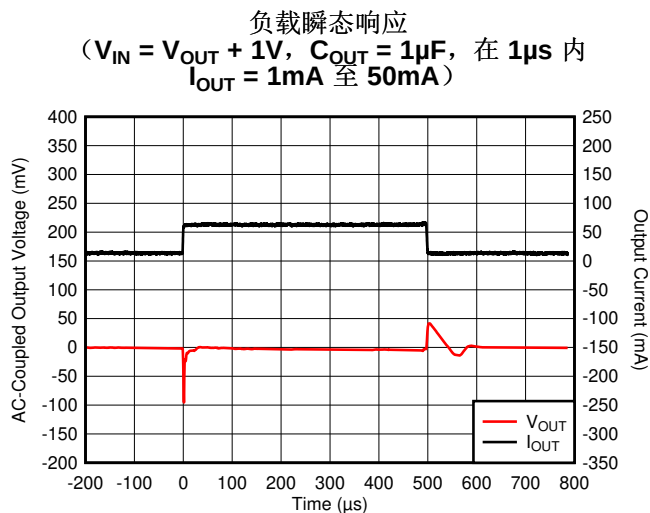
# 具有快速瞬态响应的 TPS7A02 毫微功耗 $I_Q$ 、25nA、200mA、低压降稳压器

## 1 特性

- 超低  $I_Q$ : 25nA (典型值), 即使处于压降状态
- 关断  $I_Q$ : 3nA (典型值)
- 出色的瞬态响应 (1mA 至 50mA)
  - 建立时间小于 10 $\mu$ s
  - 100mV 下冲
- 封装:
  - 1.0mm  $\times$  1.0mm X2SON
  - SOT23-5
  - 0.64mm  $\times$  0.64mm DSBGA (预发布)
- 输入电压范围: 1.5V 至 6.0V
- 输出电压范围: 0.8V 至 5.0V (固定)
- 输出精度: 在工作温度范围内为 1.5%
- 智能使能端下拉
- 超低压降:
  - 在 200mA 下为 270mV (最大值) ( $V_{OUT} = 3.3V$ )
- 与 1 $\mu$ F 或更大的电容器一起工作时保持稳定

## 2 应用

- 可穿戴电子产品
- 恒温器、烟雾和热量探测器
- 燃气表、热量表和水表
- 血糖监测仪和脉动式血氧计
- 住宅断路器和故障指示灯
- 楼宇安全和视频监控设备
- EPOS 读卡器



## 3 说明

TPS7A02 是一款超小型、超低静态电流低压降线性稳压器 (LDO), 可提供 200mA 的电流以及出色的瞬态性能。

TPS7A02 具有超低  $I_Q$  (25nA), 专为将超低静态电流作为关键参数的应用而设计。此器件即使在压降模式下也能保持低  $I_Q$  消耗, 以进一步延长电池寿命。在关断模式或禁用模式下, 该器件消耗超低 (3nA  $I_Q$ ), 有助于延长电池货架期。TPS7A02 输出电压范围为 0.8V 至 5.0V, 步长为 50mV, 以支持更低的现代微控制器 (MCU) 内核电压。

TPS7A02 配备具有内部控制下拉电阻的智能使能电路, 该电阻即使在 EN 引脚悬空时也能保持 LDO 处于禁用状态, 有助于最大限度减少用于下拉 EN 引脚的外部组件。此电路还有助于在器件处于禁用状态时最大限度减小外部下拉电路中流过的电流。

TPS7A02 的额定工作温度范围为  $T_J = -40^\circ C$  至  $+125^\circ C$ 。

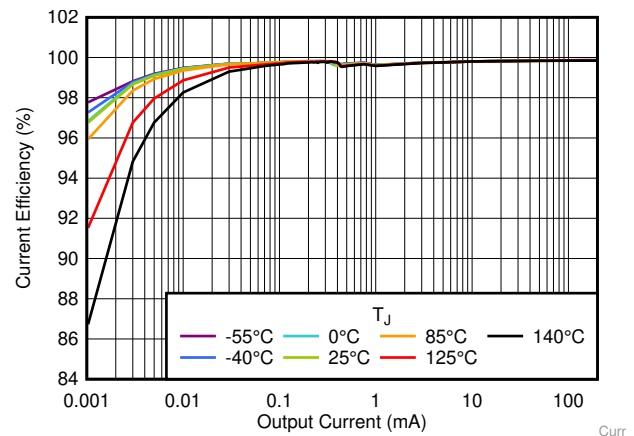
器件信息<sup>(1)</sup>

| 器件型号    | 封装                       | 封装尺寸 (标称值)             |
|---------|--------------------------|------------------------|
| TPS7A02 | X2SON (4)                | 1.00mm $\times$ 1.00mm |
|         | DSBGA (4) <sup>(2)</sup> | 0.64mm $\times$ 0.64mm |
|         | SOT-23 (5)               | 2.90mm $\times$ 1.60mm |

(1) 如需了解所有可用封装, 请参阅数据表末尾的封装选项附录。

(2) 预发布封装。

接地电流效率与输出电流间的关系



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## 4 修订历史记录

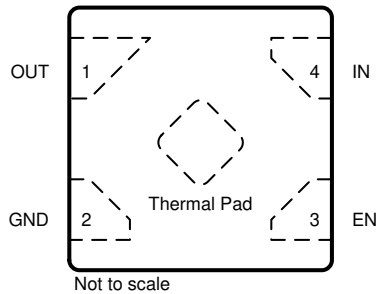
注：之前版本的页码可能与当前版本有所不同。

| <b>Changes from Revision A (December 2019) to Revision B</b> | <b>Page</b> |
|--------------------------------------------------------------|-------------|
| • 已更改 将 DBV (SOT23-5) 封装从“预发布”更改为“生产数据” .....                | <b>1</b>    |

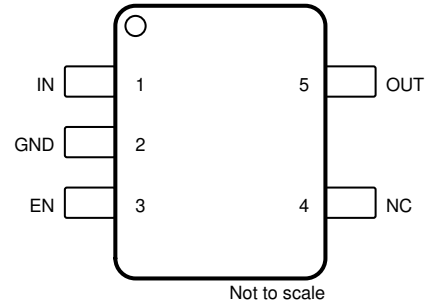
| <b>Changes from Original (July 2019) to Revision A</b> | <b>Page</b> |
|--------------------------------------------------------|-------------|
| • 已更改 将器件状态从“预告信息”更改为“生产数据” .....                      | <b>1</b>    |

## 5 Pin Configuration and Functions

**DQN Package**  
1-mm × 1-mm, 4-pin X2SON  
Top View



**DBV Package**  
5-Pin SOT-23  
Top View



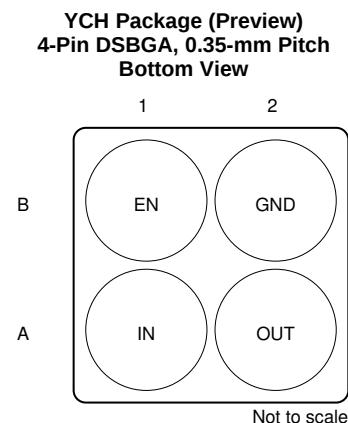
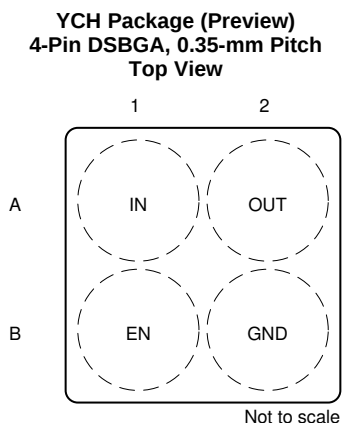
**Pin Functions: DQN, DBV**

| NAME        | PIN |     | I/O <sup>(1)</sup> | DESCRIPTION                                                                                                                                                                                                                                                                                                                                    |
|-------------|-----|-----|--------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
|             | DQN | DBV |                    |                                                                                                                                                                                                                                                                                                                                                |
| EN          | 3   | 3   | Input              | Enable pin. Driving this pin to logic high enables the device; driving this pin to logic low or floating this pin disables the device. This pin features an internal pulldown resistor, which is disconnected when EN is driven high externally and the device has started up.                                                                 |
| GND         | 2   | 2   | —                  | Ground pin. This pin must be connected to ground on the board.                                                                                                                                                                                                                                                                                 |
| IN          | 4   | 1   | Input              | Input pin. For best transient response and to minimize input impedance, use the recommended value or larger ceramic capacitor from IN to ground; see the <a href="#">Recommended Operating Conditions</a> table. Place the input capacitor as close to the input of the device as possible.                                                    |
| NC          | —   | 4   | —                  | No connect pin. This pin is not internally connected. Connect to ground or leave floating.                                                                                                                                                                                                                                                     |
| OUT         | 1   | 5   | Output             | Regulated output pin. A 0.5-μF or greater effective capacitance is required from OUT to ground for stability. For best transient response, use a 1-μF or larger ceramic capacitor from OUT to ground. Place the output capacitor as close to output of the device as possible; see the <a href="#">Recommended Operating Conditions</a> table. |
| Thermal pad | —   | —   | —                  | Connect the thermal pad to a large-area ground plane. The thermal pad is internally connect to ground.                                                                                                                                                                                                                                         |

(1) NC = No internal connection.

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### Pin Functions: YCH

| PIN  |     | I/O    | DESCRIPTION                                                                                                                                                                                                                                                                                                                                    |
|------|-----|--------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| NAME | YCH |        |                                                                                                                                                                                                                                                                                                                                                |
| EN   | B1  | Input  | Enable pin. Driving this pin to logic high enables the device; driving this pin to logic low or floating this pin disables the device. This pin features an internal pulldown resistor, which is disconnected when EN is driven high externally and the device has started up.                                                                 |
| GND  | B2  | —      | Ground pin. This pin must be connected to ground and the thermal pad.                                                                                                                                                                                                                                                                          |
| IN   | A1  | Input  | Input pin. For best transient response and to minimize input impedance, use the recommended value or larger ceramic capacitor from IN to ground; see the <a href="#">Recommended Operating Conditions</a> table. Place the input capacitor as close to input of the device as possible.                                                        |
| OUT  | A2  | Output | Regulated output pin. A 0.5-μF or greater effective capacitance is required from OUT to ground for stability. For best transient response, use a 1-μF or larger ceramic capacitor from OUT to ground. Place the output capacitor as close to output of the device as possible; see the <a href="#">Recommended Operating Conditions</a> table. |

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

|             |                                    | MIN                | MAX                                         | UNIT |
|-------------|------------------------------------|--------------------|---------------------------------------------|------|
| Voltage     | V <sub>IN</sub>                    | −0.3               | 6.5                                         | V    |
|             | V <sub>EN</sub>                    | −0.3               | 6.5                                         |      |
|             | V <sub>OUT</sub>                   | −0.3               | V <sub>IN</sub> + 0.3 or 5.5 <sup>(2)</sup> |      |
| Current     | Maximum output                     | Internally limited |                                             | A    |
| Temperature | Operating junction, T <sub>J</sub> | −40                | 150                                         | °C   |
|             | Storage, T <sub>stg</sub>          | −65                | 150                                         |      |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Maximum is V<sub>IN</sub> + 0.3 V or 5.5 V, whichever is smaller.

### 6.2 ESD Ratings

|                    |                         | VALUE                                                                          | UNIT  |
|--------------------|-------------------------|--------------------------------------------------------------------------------|-------|
| V <sub>(ESD)</sub> | Electrostatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>              | ±1000 |
|                    |                         | Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup> | ±500  |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

over operating junction temperature range (unless otherwise noted)

|                  |                                     | MIN | NOM | MAX | UNIT |
|------------------|-------------------------------------|-----|-----|-----|------|
| V <sub>IN</sub>  | Input voltage                       | 1.5 |     | 6.0 | V    |
| V <sub>EN</sub>  | Enable voltage                      | 0   |     | 6.0 | V    |
| V <sub>OUT</sub> | Output voltage                      | 0.8 |     | 5.0 | V    |
| I <sub>OUT</sub> | Output current                      | 0   |     | 200 | mA   |
| C <sub>IN</sub>  | Input capacitor                     |     | 1   |     | μF   |
| C <sub>OUT</sub> | Output capacitor <sup>(1)</sup> (2) | 1   | 1   | 22  | μF   |
| F <sub>EN</sub>  | EN toggle frequency                 |     |     | 10  | kHz  |
| T <sub>J</sub>   | Operating junction temperature      | −40 |     | 125 | °C   |

- (1) Effective output capacitance of 0.5 μF minimum required for stability.
- (2) 22 μF is the maximum derated capacitance that can be used for stability.

### 6.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |                                              | TPS7A02     |                |             | UNIT |
|-------------------------------|----------------------------------------------|-------------|----------------|-------------|------|
|                               |                                              | DQN (X2SON) | DBV (SOT-23-5) | YCH (DSBGA) |      |
|                               |                                              | 4 PINS      | 5 PINS         | 4 PINS      |      |
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance       | 179.1       | 181.9          | TBD         | °C/W |
| R <sub>θJC(top)</sub>         | Junction-to-case(top) thermal resistance     | 137.6       | 53.0           | TBD         | °C/W |
| R <sub>θJB</sub>              | Junction-to-board thermal resistance         | 116.3       | 88.1           | TBD         | °C/W |
| ψ <sub>JT</sub>               | Junction-to-top characterization parameter   | 6.1         | 27.1           | TBD         | °C/W |
| ψ <sub>JB</sub>               | Junction-to-board characterization parameter | 116.3       | 52.7           | TBD         | °C/W |
| R <sub>θJC(bot)</sub>         | Junction-to-case(bottom) thermal resistance  | 112.3       | N/A            | TBD         | °C/W |

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

**TPS7A02**

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**6.5 Electrical Characteristics**

Specified at  $T_J = -40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ ,  $V_{IN} = V_{OUT(nom)} + 0.5\text{ V}$  or  $2.0\text{ V}$  (whichever is greater),  $I_{OUT} = 1\text{ mA}$ ,  $V_{EN} = V_{IN}$ , and  $C_{IN} = C_{OUT} = 1\text{ }\mu\text{F}$  (unless otherwise noted). Typical values are at  $T_J = 25^{\circ}\text{C}$ .

| PARAMETER                        |                                          | TEST CONDITIONS                                                                                                       |                                                                                       | MIN  | TYP  | MAX  | UNIT                       |
|----------------------------------|------------------------------------------|-----------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------|------|------|------|----------------------------|
|                                  | Nominal accuracy                         | $T_J = 25^{\circ}\text{C}$ , $V_{OUT} \geq 1.5\text{ V}$ , $1\text{ }\mu\text{A}^{(1)} \leq I_{OUT} \leq 1\text{ mA}$ |                                                                                       | -1   |      | 1    | %                          |
|                                  |                                          | $T_J = 25^{\circ}\text{C}$ ; $V_{OUT} < 1.5\text{ V}$                                                                 |                                                                                       | -15  |      | 15   | mV                         |
|                                  | Accuracy over temperature                | $V_{OUT} \geq 1.5\text{ V}$                                                                                           | $T_J = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$                                 | -1.5 |      | 1.5  | %                          |
|                                  |                                          | $V_{OUT} < 1.5\text{ V}$                                                                                              |                                                                                       | -20  |      | 20   | mV                         |
| $\Delta V_{OUT}(\Delta V_{IN})$  | Line regulation                          | $V_{OUT(nom)} + 0.5\text{ V} \leq V_{IN} \leq 6.0\text{ V}^{(2)}$                                                     | $T_J = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$                                 |      |      | 5    | mV                         |
| $\Delta V_{OUT}(\Delta I_{OUT})$ | Load regulation <sup>(3)</sup>           | $1\text{ mA} \leq I_{OUT} \leq 200\text{ mA}$ ,<br>$V_{IN} = V_{OUT(nom)} + 0.5\text{ V}^{(2)}$                       | $T_J = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$                                  | 20   |      | 38   | mV                         |
|                                  |                                          |                                                                                                                       | $T_J = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$                                 |      |      | 50   |                            |
| $I_{GND}$                        | Ground current                           | $I_{OUT} = 0\text{ mA}$                                                                                               | $T_J = 25^{\circ}\text{C}$                                                            | 25   |      | 46   | nA                         |
|                                  |                                          |                                                                                                                       | $T_J = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$                                  |      |      | 60   |                            |
| $I_{GND}/I_{OUT}$                | Ground current vs load current           | $5\text{ }\mu\text{A} \leq I_{OUT} < 1\text{ mA}$                                                                     | $T_J = 25^{\circ}\text{C}$                                                            | 1    |      |      | %                          |
|                                  |                                          | $1\text{ mA} \leq I_{OUT} < 100\text{ mA}$                                                                            |                                                                                       | 0.25 |      |      |                            |
|                                  |                                          | $I_{OUT} \geq 100\text{ mA}$                                                                                          |                                                                                       | 0.15 |      |      |                            |
| $I_{GND(Do)}$                    | Ground current in dropout <sup>(1)</sup> | $I_{OUT} = 0\text{ mA}$ , $V_{IN} = 95\% \times V_{OUT(NOM)}$                                                         | $T_J = 25^{\circ}\text{C}$                                                            | 25   |      |      | nA                         |
| $I_{SHDN}$                       | Shutdown current                         | $V_{EN} = 0\text{ V}$ , $1.5\text{ V} \leq V_{IN} \leq 5.0\text{ V}$ , $T_J = 25^{\circ}\text{C}$                     |                                                                                       | 3    |      | 10   | nA                         |
| $I_{CL}$                         | Output current limit                     | $V_{OUT} = 90\% \times V_{OUT(nom)}$                                                                                  | $V_{OUT} < 2.5\text{ V}$ ,<br>$V_{IN} = V_{OUT(nom)} + V_{DO(max)} + 1.0\text{ V}$    | 240  | 450  | 750  | mA                         |
|                                  |                                          |                                                                                                                       | $V_{OUT} \geq 2.5\text{ V}$ ,<br>$V_{IN} = V_{OUT(nom)} + V_{DO(max)} + 0.5\text{ V}$ | 240  | 450  | 750  | mA                         |
| $I_{SC}$                         | Short-circuit current limit              | $V_{OUT} = 0\text{ V}$                                                                                                |                                                                                       | 65   |      |      | mA                         |
| $V_{DO}$                         | Dropout voltage <sup>(4)</sup>           | $T_J = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$                                                                  | $0.8\text{ V} \leq V_{OUT} < 1.0\text{ V}$                                            |      |      | 1050 | mV                         |
|                                  |                                          |                                                                                                                       | $1.0\text{ V} \leq V_{OUT} < 1.2\text{ V}$                                            |      |      | 790  |                            |
|                                  |                                          |                                                                                                                       | $1.2\text{ V} \leq V_{OUT} < 1.5\text{ V}$                                            |      |      | 650  |                            |
|                                  |                                          |                                                                                                                       | $1.5\text{ V} \leq V_{OUT} < 1.8\text{ V}$                                            |      |      | 490  |                            |
|                                  |                                          |                                                                                                                       | $1.8\text{ V} \leq V_{OUT} < 2.5\text{ V}$                                            |      |      | 400  |                            |
|                                  |                                          |                                                                                                                       | $2.5\text{ V} \leq V_{OUT} < 3.3\text{ V}$                                            |      |      | 310  |                            |
|                                  |                                          |                                                                                                                       | $3.3\text{ V} \leq V_{OUT} \leq 5.0\text{ V}$                                         |      |      | 270  |                            |
|                                  |                                          | $T_J = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$                                                                 | $0.8\text{ V} \leq V_{OUT} < 1.0\text{ V}$                                            |      |      | 1100 |                            |
|                                  |                                          |                                                                                                                       | $1.0\text{ V} \leq V_{OUT} < 1.2\text{ V}$                                            |      |      | 850  |                            |
|                                  |                                          |                                                                                                                       | $1.2\text{ V} \leq V_{OUT} < 1.5\text{ V}$                                            |      |      | 700  |                            |
|                                  |                                          |                                                                                                                       | $1.5\text{ V} \leq V_{OUT} < 1.8\text{ V}$                                            |      |      | 560  |                            |
|                                  |                                          |                                                                                                                       | $1.8\text{ V} \leq V_{OUT} < 2.5\text{ V}$                                            |      |      | 450  |                            |
|                                  |                                          |                                                                                                                       | $2.5\text{ V} \leq V_{OUT} < 3.3\text{ V}$                                            |      |      | 360  |                            |
|                                  |                                          |                                                                                                                       | $3.3\text{ V} \leq V_{OUT} \leq 5.0\text{ V}$                                         |      |      | 310  |                            |
| PSRR                             | Power-supply rejection ratio             | $f = 1\text{ kHz}$ , $I_{OUT} = 30\text{ mA}$                                                                         |                                                                                       | 55   |      |      | dB                         |
| $V_N$                            | Output voltage noise                     | $\text{BW} = 10\text{ Hz}$ to $100\text{ kHz}$ , $V_{OUT} = 0.8\text{ V}$ , $I_{OUT} = 30\text{ mA}$                  |                                                                                       | 130  |      |      | $\mu\text{V}_{\text{RMS}}$ |
| $V_{UVLO}$                       | UVLO threshold                           | $V_{IN}$ rising                                                                                                       |                                                                                       | 1.23 | 1.3  | 1.47 | V                          |
|                                  |                                          | $V_{IN}$ falling                                                                                                      |                                                                                       | 1.0  | 1.12 | 1.41 |                            |

(1) Specified by design

(2)  $V_{IN} = 2.0\text{ V}$  for  $V_{OUT} \leq 1.5\text{ V}$ .

(3) Load Regulation is normalized to the output voltage at  $I_{OUT} = 1\text{ mA}$ .

(4) Dropout is measured by ramping  $V_{IN}$  down until  $V_{OUT} = V_{OUT(nom)} \times 95\%$ , with  $I_{OUT} = 200\text{ mA}$ .

## Electrical Characteristics (continued)

Specified at  $T_J = -40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ ,  $V_{IN} = V_{OUT(nom)} + 0.5\text{ V}$  or  $2.0\text{ V}$  (whichever is greater),  $I_{OUT} = 1\text{ mA}$ ,  $V_{EN} = V_{IN}$ , and  $C_{IN} = C_{OUT} = 1\text{ }\mu\text{F}$  (unless otherwise noted). Typical values are at  $T_J = 25^{\circ}\text{C}$ .

| PARAMETER          |                                    | TEST CONDITIONS                           | MIN | TYP | MAX | UNIT               |
|--------------------|------------------------------------|-------------------------------------------|-----|-----|-----|--------------------|
| $V_{UVLO(HYST)}$   | UVLO hysteresis                    | $V_{IN}$ hysteresis                       |     | 180 |     | mV                 |
| $V_{EN(HI)}$       | EN pin logic high voltage          |                                           | 1.1 |     |     | V                  |
| $V_{EN(LOW)}$      | EN pin logic low voltage           |                                           |     |     | 0.3 | V                  |
| $I_{EN}$           | EN pin leakage current             | $V_{EN} = V_{IN} = 6.0\text{ V}$          |     | 10  |     | nA                 |
| $R_{EN(PULLDOWN)}$ | Smart enable pulldown resistor     | $V_{EN} = 0.3\text{ V}$                   |     | 500 |     | $\text{K}\Omega$   |
| $R_{PULLDOWN}$     | Pulldown resistor                  | $V_{IN} = 3.3\text{ V}$ , device disabled |     | 60  |     | $\Omega$           |
| $T_{SD(shutdown)}$ | Thermal shutdown temperature       | Shutdown, temperature increasing          |     | 170 |     | $^{\circ}\text{C}$ |
| $T_{SD(reset)}$    | Thermal shutdown reset temperature | Reset, temperature decreasing             |     | 145 |     |                    |

## 6.6 Switching Characteristics

Specified at  $T_J = -40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ ,  $V_{IN} = V_{OUT(nom)} + 0.5\text{ V}$  or  $2.0\text{ V}$  (whichever is greater),  $I_{OUT} = 1\text{ mA}$ ,  $V_{EN} = V_{IN}$ , and  $C_{IN} = C_{OUT} = 1\text{ }\mu\text{F}$  (unless otherwise noted). Typical values are at  $T_J = 25^{\circ}\text{C}$ .

| PARAMETER |               | TEST CONDITIONS                                           |                                               | MIN | TYP  | MAX  | UNIT          |
|-----------|---------------|-----------------------------------------------------------|-----------------------------------------------|-----|------|------|---------------|
| $t_{STR}$ | Start-up time | From EN assertion to $V_{OUT} = 90\% \times V_{OUT(nom)}$ | $0.8\text{ V} \leq V_{OUT} \leq 1.5\text{ V}$ |     | 500  | 800  | $\mu\text{s}$ |
|           |               |                                                           | $1.5\text{ V} < V_{OUT} \leq 3.0\text{ V}$    |     | 750  | 1200 |               |
|           |               |                                                           | $3.0\text{ V} < V_{OUT} \leq 5.0\text{ V}$    |     | 1200 | 1600 |               |

## 6.7 Typical Characteristics

at operating temperature range ( $T_J = -40^\circ\text{C}$  to  $125^\circ\text{C}$ ),  $V_{IN} = V_{OUT(nom)} + 0.5\text{ V}$  or  $2.0\text{ V}$  (whichever is greater),  $I_{OUT} = 1\text{ mA}$ ,  $V_{EN} = V_{IN}$ , and  $C_{IN} = C_{OUT} = 1\text{ }\mu\text{F}$  (unless otherwise noted)

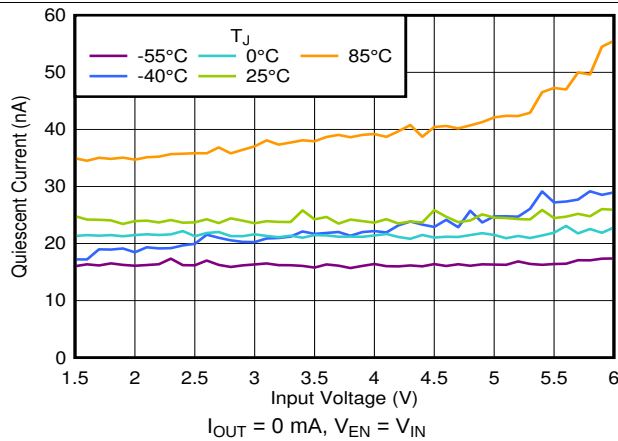


图 1.  $I_Q$  vs  $V_{IN}$  and Temperature

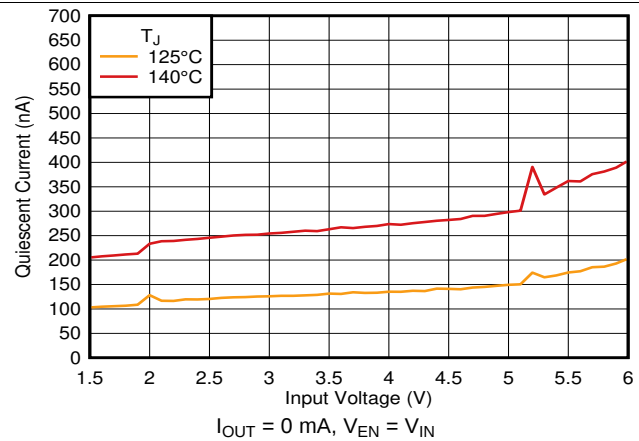


图 2.  $I_Q$  vs  $V_{IN}$  and Temperature

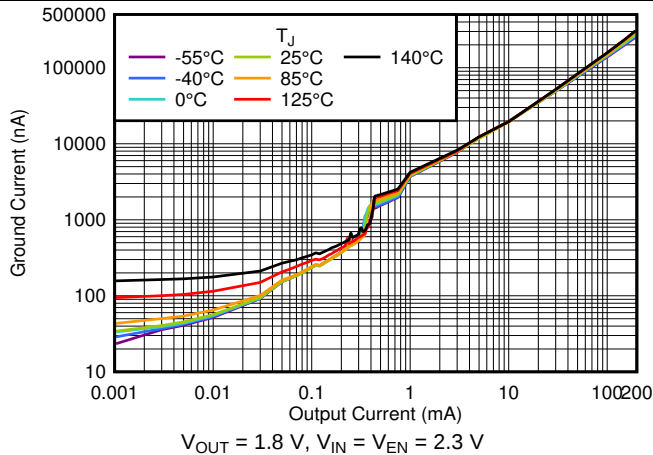


图 3.  $I_Q$  vs  $I_{OUT}$  and Temperature up to 200 mA

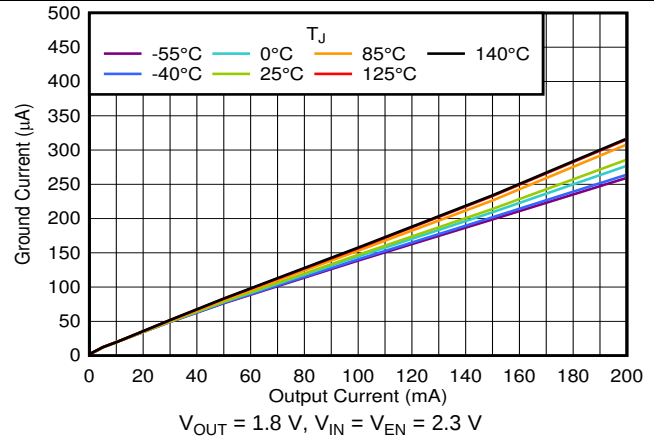


图 4.  $I_Q$  vs  $I_{OUT}$  and Temperature Up to 200 mA

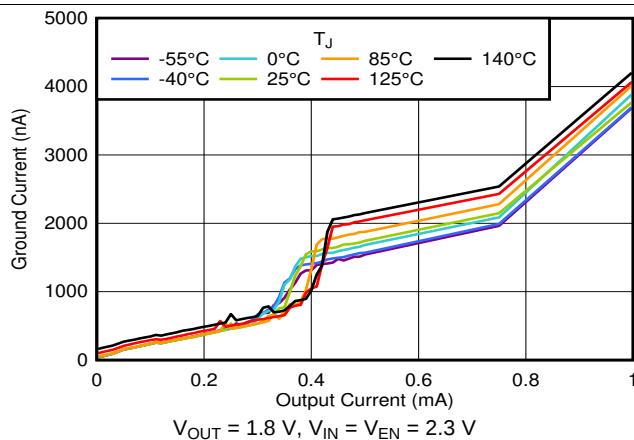


图 5.  $I_Q$  vs  $I_{OUT}$  and Temperature Up to 1 mA

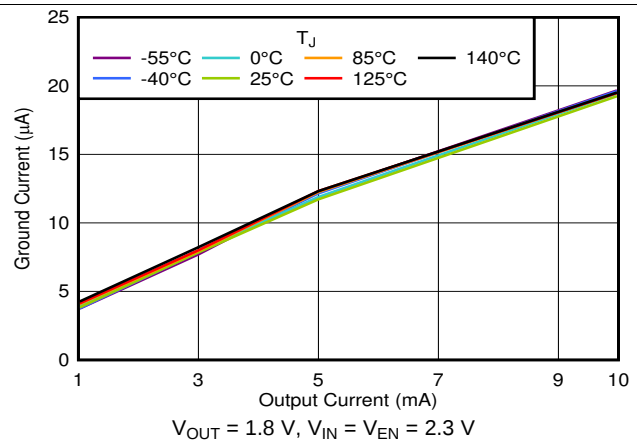


图 6.  $I_Q$  vs  $I_{OUT}$  and Temperature for 1 mA to 10 mA

## Typical Characteristics (接下页)

at operating temperature range ( $T_J = -40^\circ\text{C}$  to  $125^\circ\text{C}$ ),  $V_{IN} = V_{OUT(nom)} + 0.5\text{ V}$  or  $2.0\text{ V}$  (whichever is greater),  $I_{OUT} = 1\text{ mA}$ ,  $V_{EN} = V_{IN}$ , and  $C_{IN} = C_{OUT} = 1\text{ }\mu\text{F}$  (unless otherwise noted)

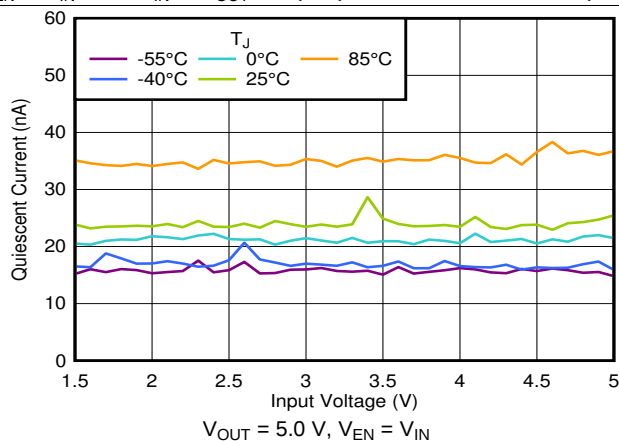


图 7.  $I_Q$  in Dropout vs  $V_{IN}$  and Temperature

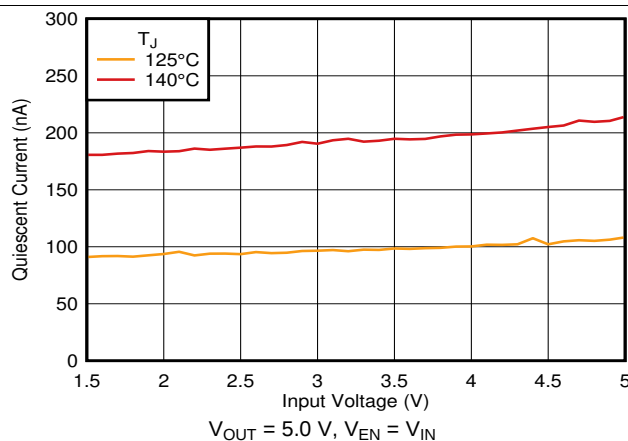


图 8.  $I_Q$  in Dropout vs  $V_{IN}$  and Temperature

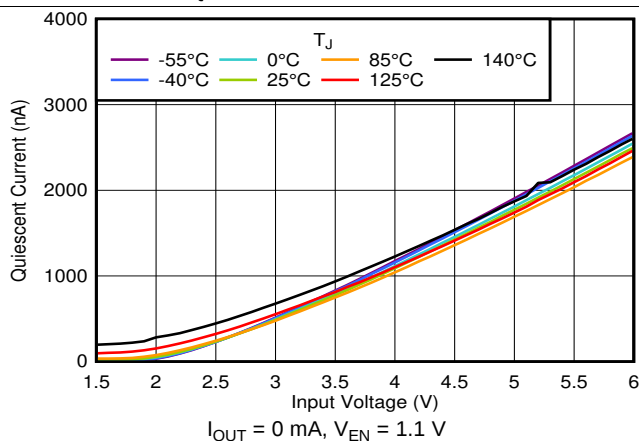


图 9.  $I_Q$  vs  $V_{IN}$  and Temperature

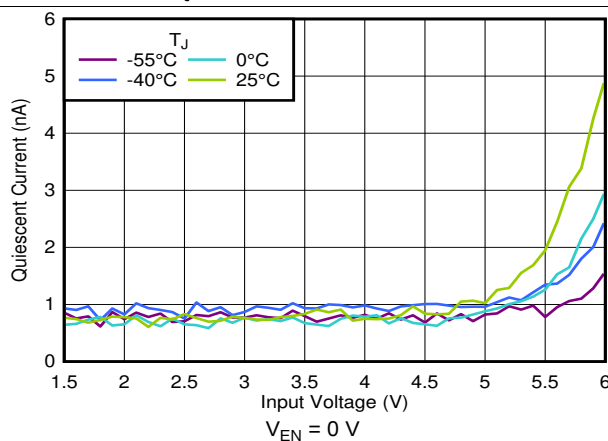


图 10.  $I_{SHDN}$  vs  $V_{IN}$  and Temperature

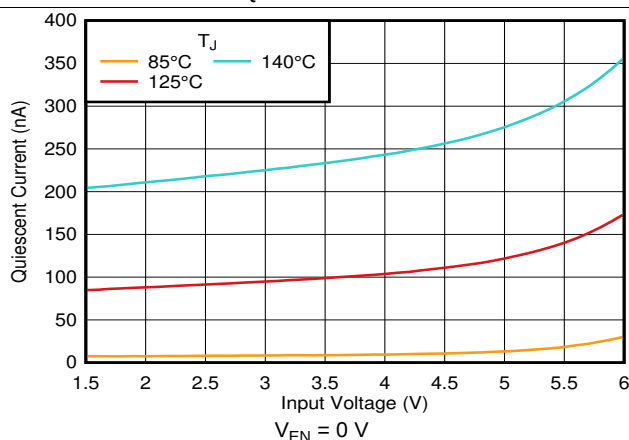


图 11.  $I_{SHDN}$  vs  $V_{IN}$  and Temperature

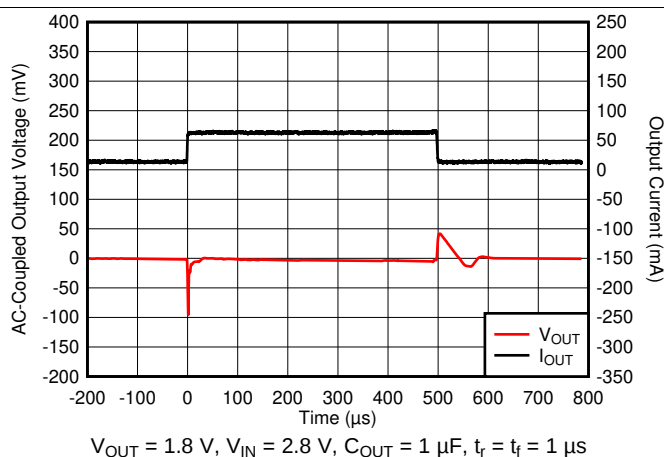


图 12.  $I_{OUT}$  Transient From 1 mA to 50 mA

## Typical Characteristics (接下页)

at operating temperature range ( $T_J = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ ),  $V_{IN} = V_{OUT(nom)} + 0.5\text{ V}$  or  $2.0\text{ V}$  (whichever is greater),  $I_{OUT} = 1\text{ mA}$ ,  $V_{EN} = V_{IN}$ , and  $C_{IN} = C_{OUT} = 1\text{ }\mu\text{F}$  (unless otherwise noted)

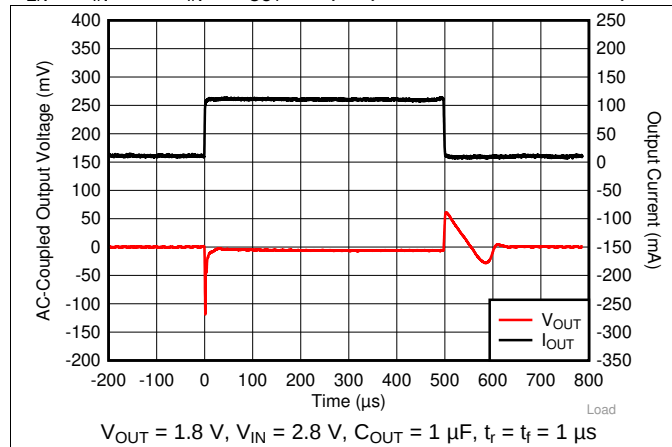


图 13.  $I_{OUT}$  Transient From 1 mA to 100 mA

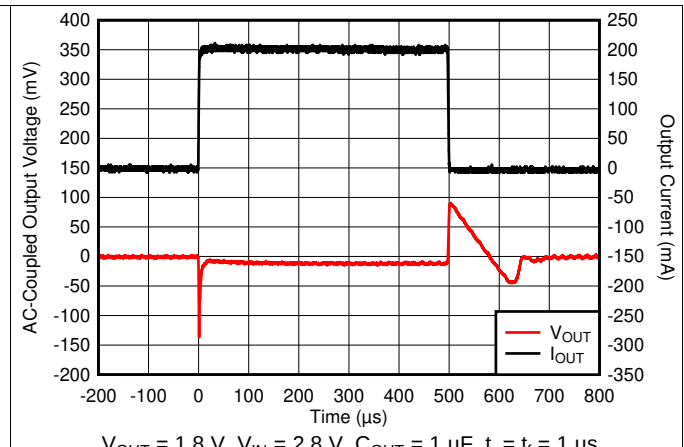


图 14.  $I_{OUT}$  Transient From 1 mA to 200 mA

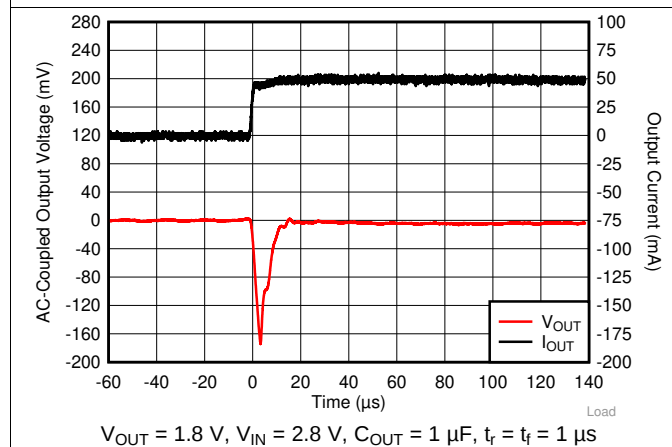


图 15.  $I_{OUT}$  Transient From 0 mA to 50 mA

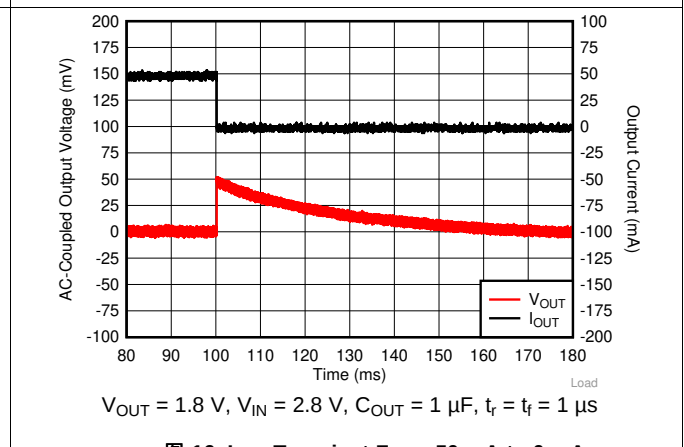


图 16.  $I_{OUT}$  Transient From 50 mA to 0 mA

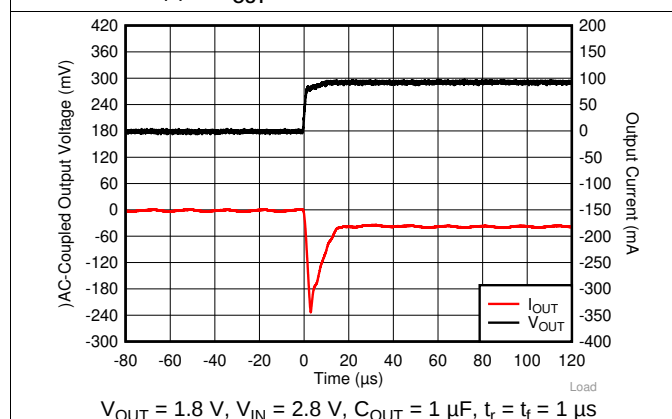


图 17.  $I_{OUT}$  Transient From 0 mA to 100 mA

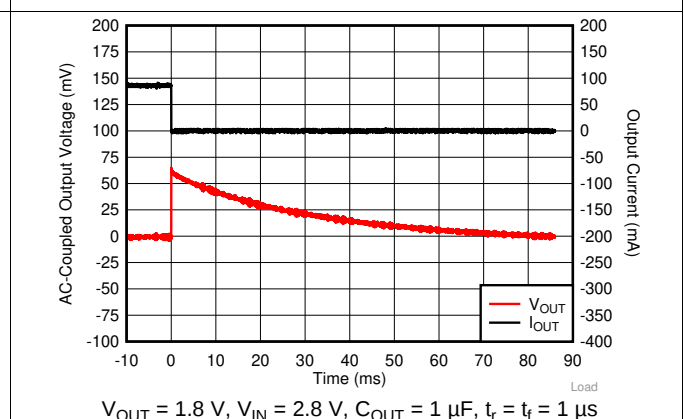


图 18.  $I_{OUT}$  Transient From 100 mA to 0 mA

## Typical Characteristics (接下页)

at operating temperature range ( $T_J = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ ),  $V_{IN} = V_{OUT(nom)} + 0.5\text{ V}$  or  $2.0\text{ V}$  (whichever is greater),  $I_{OUT} = 1\text{ mA}$ ,  $V_{EN} = V_{IN}$ , and  $C_{IN} = C_{OUT} = 1\text{ }\mu\text{F}$  (unless otherwise noted)

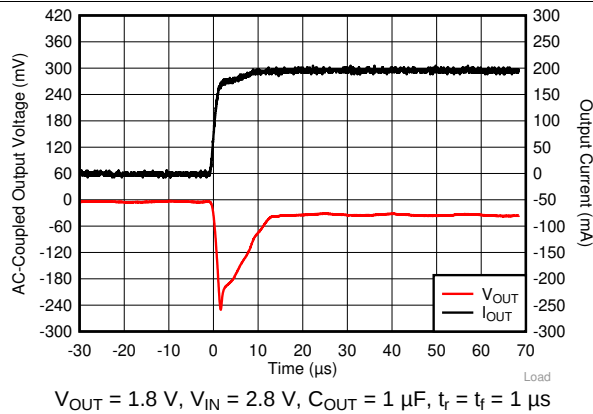


图 19.  $I_{OUT}$  Transient From 0 mA to 200 mA

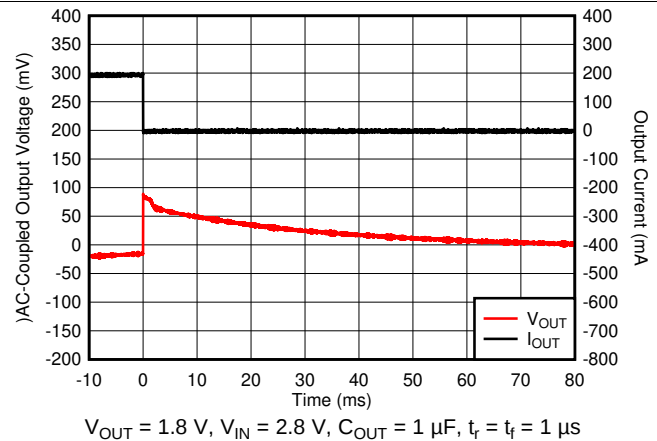


图 20.  $I_{OUT}$  Transient From 200 mA to 0 mA

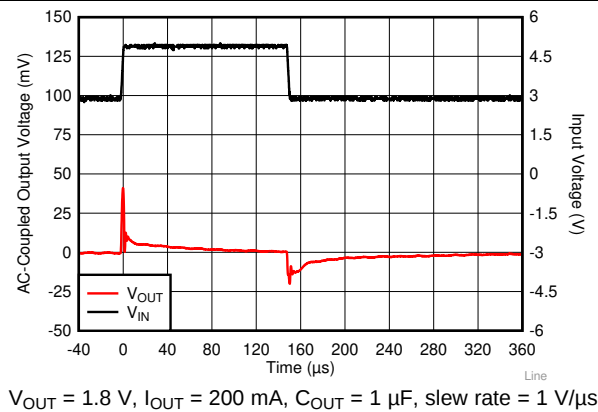


图 21.  $V_{IN}$  Transient From 2.8 V to 4.8 V

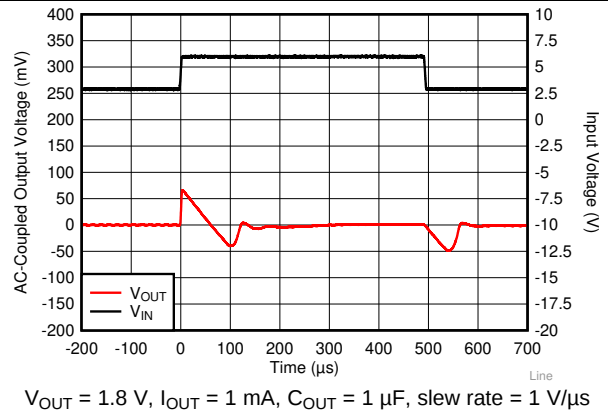


图 22.  $V_{IN}$  Transient From 2.8 V to 6.0 V

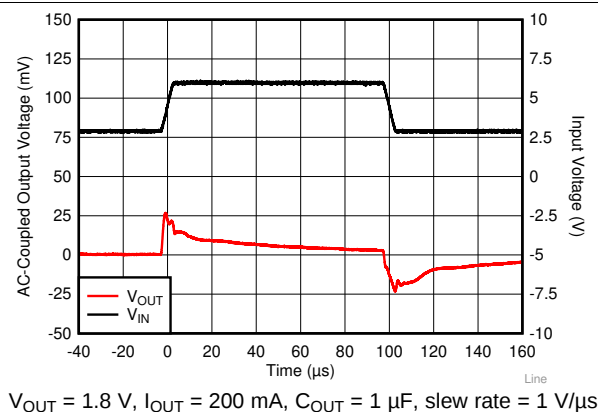


图 23.  $V_{IN}$  Transient From 2.8 V to 6.0 V

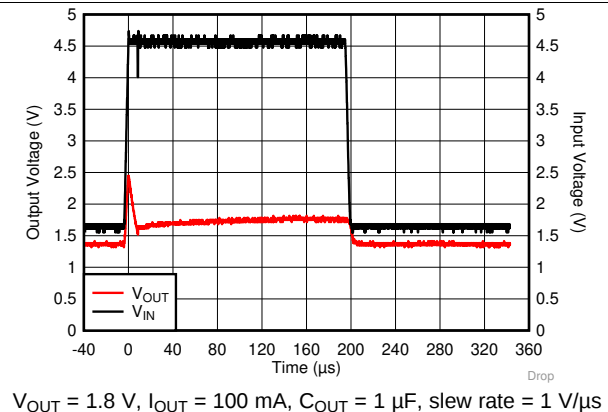


图 24.  $V_{IN}$  Transient From 1.5 V to 4.5 V

## Typical Characteristics (接下页)

at operating temperature range ( $T_J = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ ),  $V_{IN} = V_{OUT(nom)} + 0.5\text{ V}$  or  $2.0\text{ V}$  (whichever is greater),  $I_{OUT} = 1\text{ mA}$ ,  $V_{EN} = V_{IN}$ , and  $C_{IN} = C_{OUT} = 1\text{ }\mu\text{F}$  (unless otherwise noted)

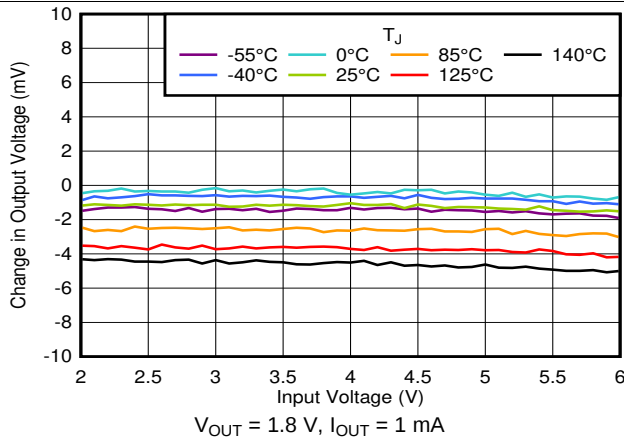


图 25. Line Regulation vs  $V_{IN}$  and Temperature

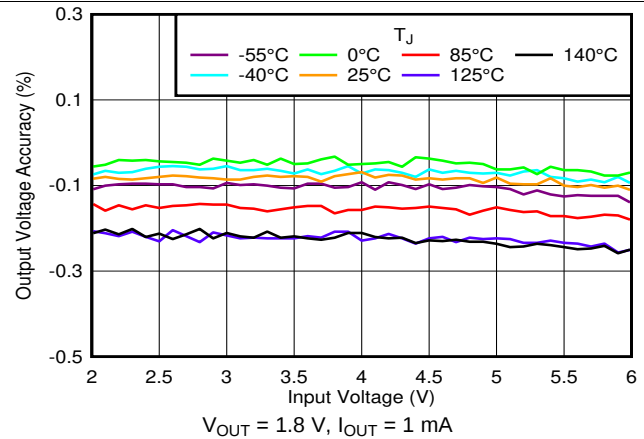


图 26. Output Accuracy vs  $V_{IN}$  and Temperature

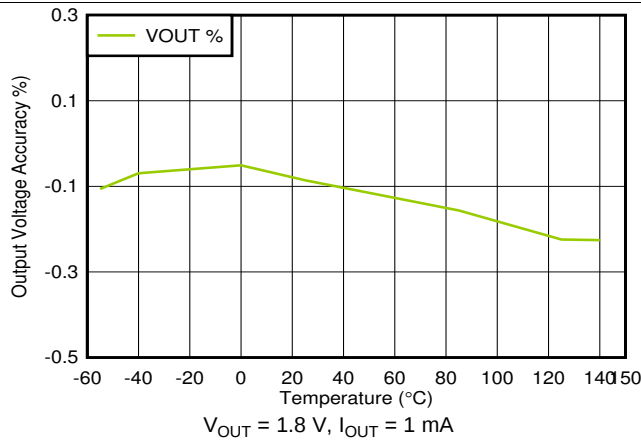


图 27. Output Accuracy vs Temperature

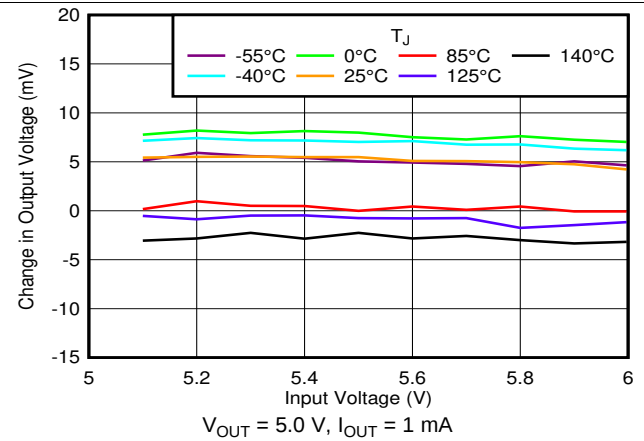


图 28. Line Regulation vs  $V_{IN}$  and Temperature

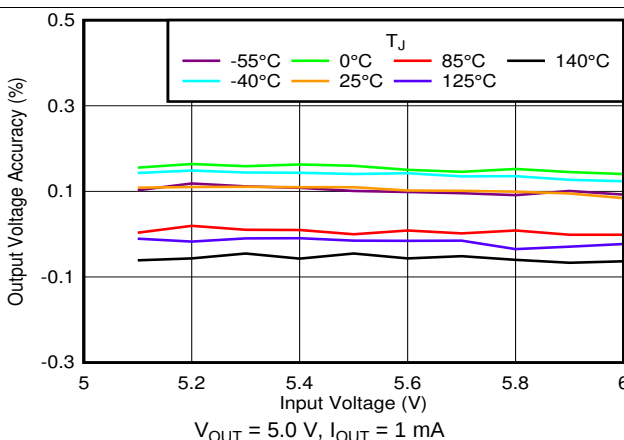


图 29. Output Accuracy vs  $V_{IN}$  and Temperature

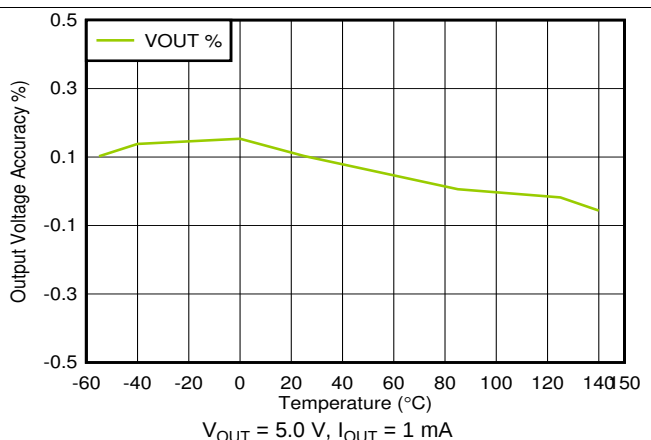


图 30. Output Accuracy vs Temperature

## Typical Characteristics (接下页)

at operating temperature range ( $T_J = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ ),  $V_{IN} = V_{OUT(nom)} + 0.5\text{ V}$  or  $2.0\text{ V}$  (whichever is greater),  $I_{OUT} = 1\text{ mA}$ ,  $V_{EN} = V_{IN}$ , and  $C_{IN} = C_{OUT} = 1\text{ }\mu\text{F}$  (unless otherwise noted)

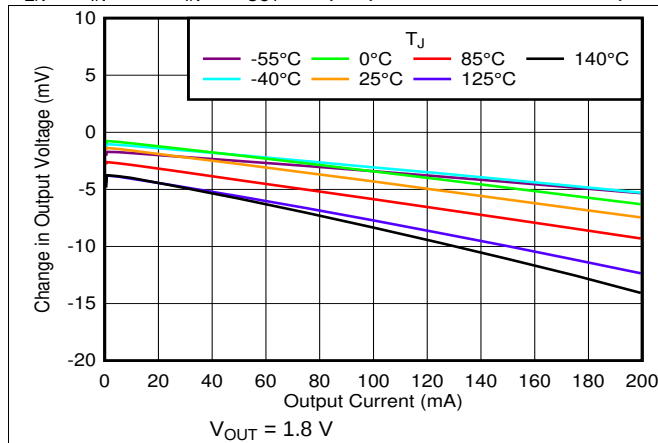


图 31. Load Regulation vs  $V_{IN}$  and Temperature

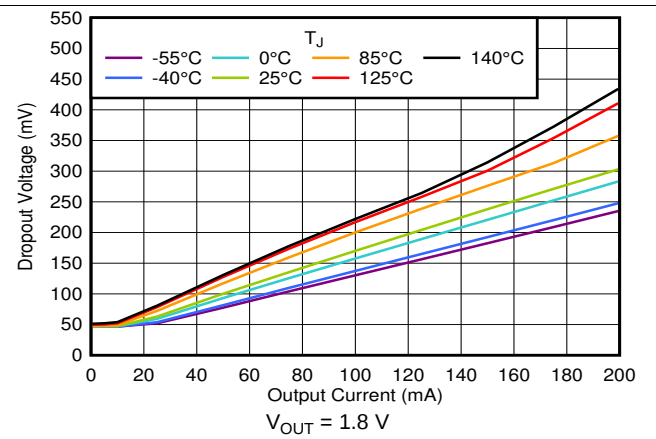


图 32. Dropout vs  $I_{OUT}$  and Temperature

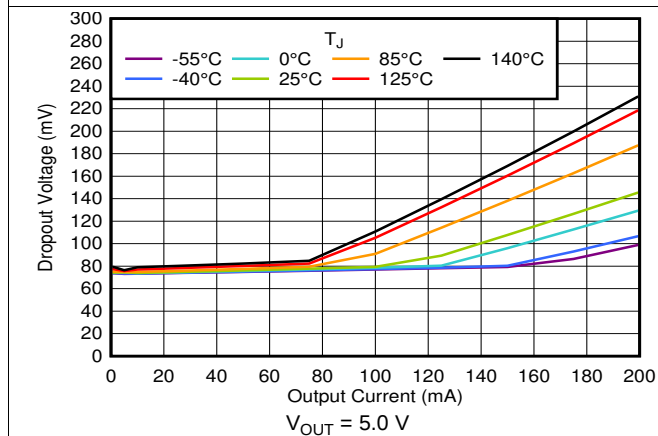


图 33. Dropout vs  $I_{OUT}$  and Temperature

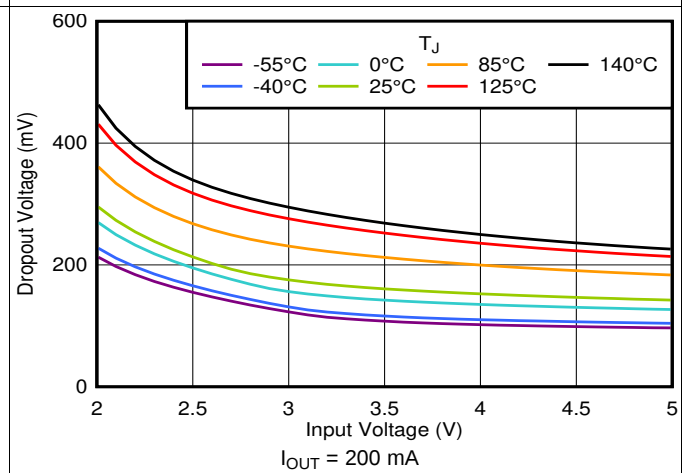


图 34. Dropout vs  $V_{IN}$  and Temperature

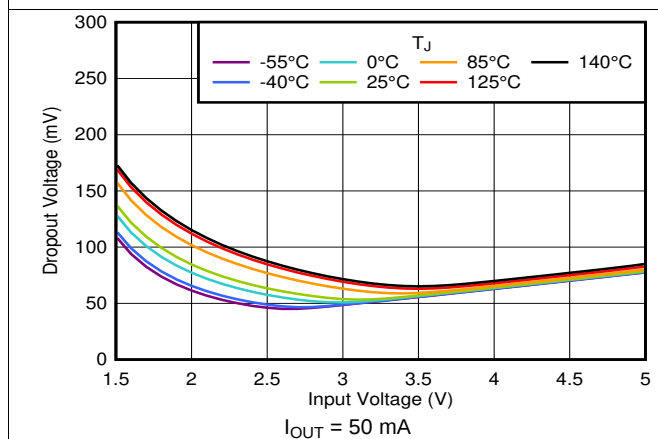


图 35. Dropout vs  $V_{IN}$  and Temperature

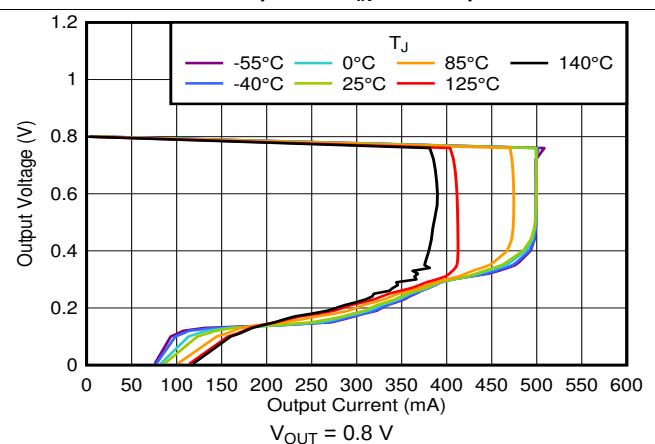


图 36. Foldback Current Limit vs  $I_{OUT}$  and Temperature

## Typical Characteristics (接下页)

at operating temperature range ( $T_J = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ ),  $V_{IN} = V_{OUT(nom)} + 0.5\text{ V}$  or  $2.0\text{ V}$  (whichever is greater),  $I_{OUT} = 1\text{ mA}$ ,  $V_{EN} = V_{IN}$ , and  $C_{IN} = C_{OUT} = 1\text{ }\mu\text{F}$  (unless otherwise noted)

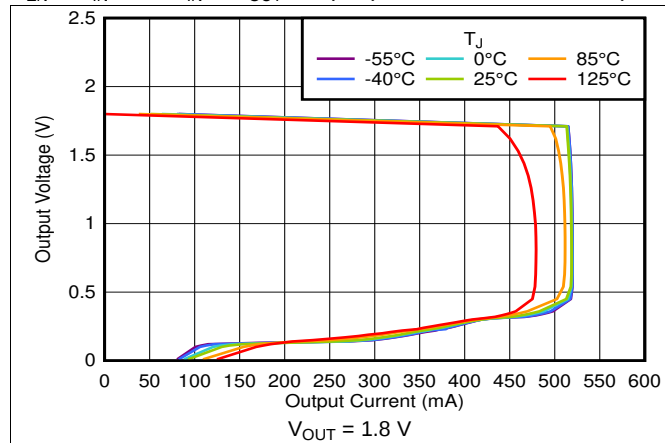


图 37. Foldback Current Limit vs  $I_{OUT}$  and Temperature

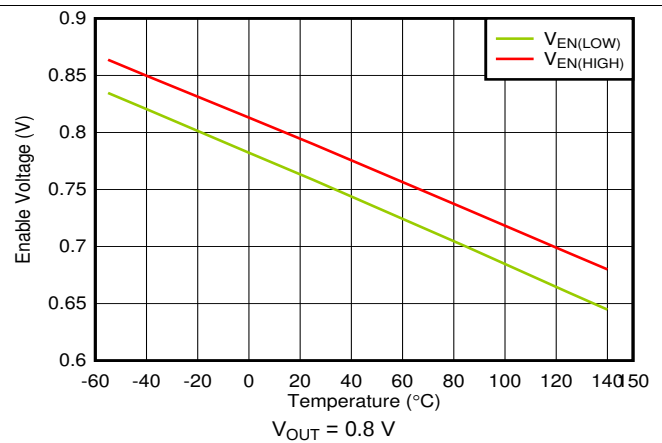


图 38. EN High and Low Threshold vs Temperature

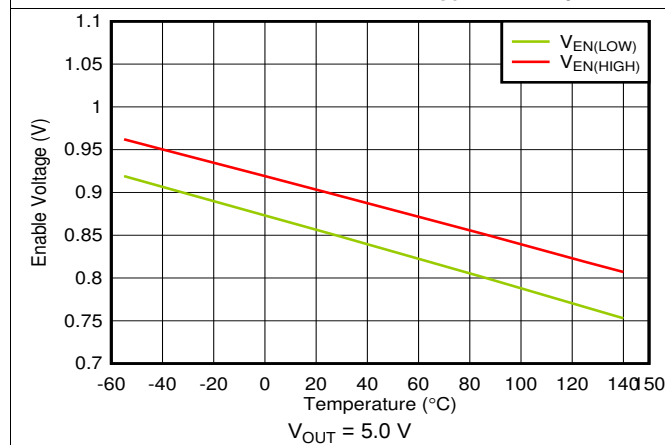


图 39. EN High and Low Threshold vs Temperature

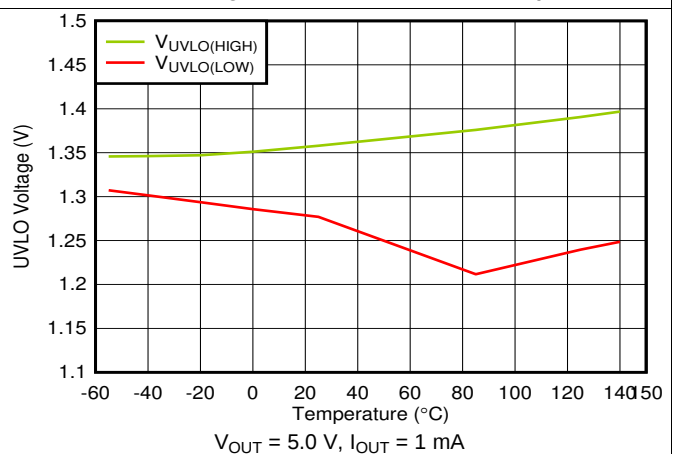


图 40. UVLO Rising and Falling Threshold vs Temperature

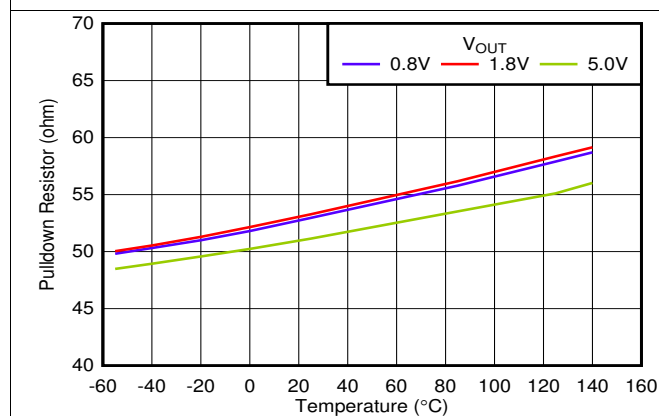


图 41. Pulldown Resistor vs Temperature and  $V_{OUT}$

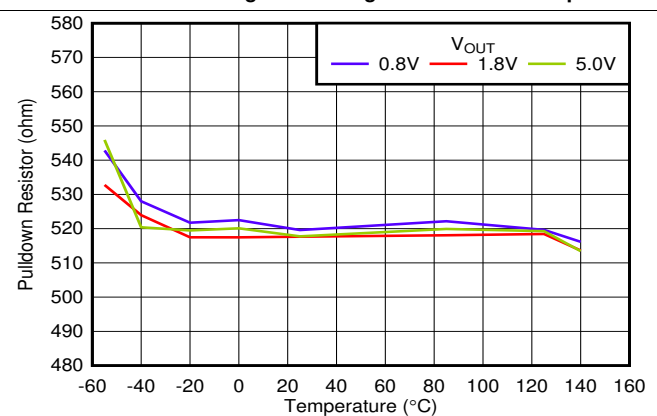


图 42. Smart Enable Pulldown Resistor vs Temperature and  $V_{OUT}$

## Typical Characteristics (接下页)

at operating temperature range ( $T_J = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ ),  $V_{IN} = V_{OUT(nom)} + 0.5\text{ V}$  or  $2.0\text{ V}$  (whichever is greater),  $I_{OUT} = 1\text{ mA}$ ,  $V_{EN} = V_{IN}$ , and  $C_{IN} = C_{OUT} = 1\text{ }\mu\text{F}$  (unless otherwise noted)

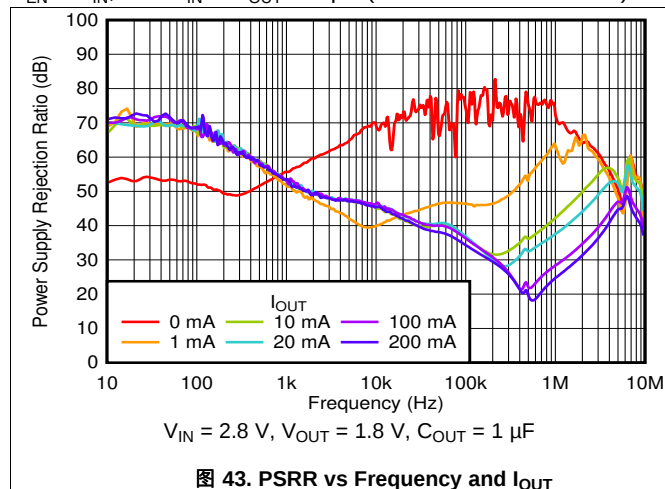


图 43. PSRR vs Frequency and  $I_{OUT}$

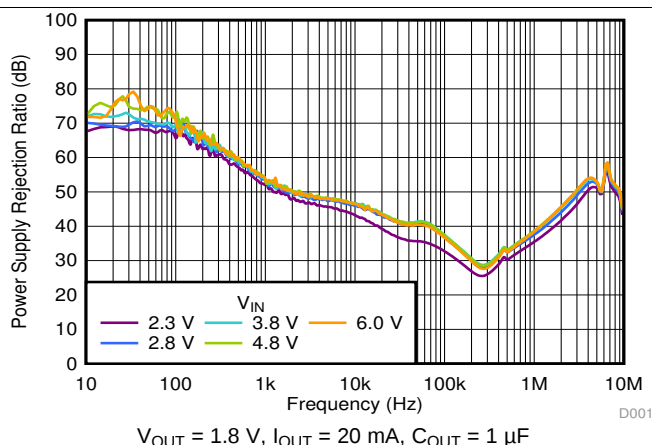


图 44. PSRR vs Frequency and  $V_{IN}$

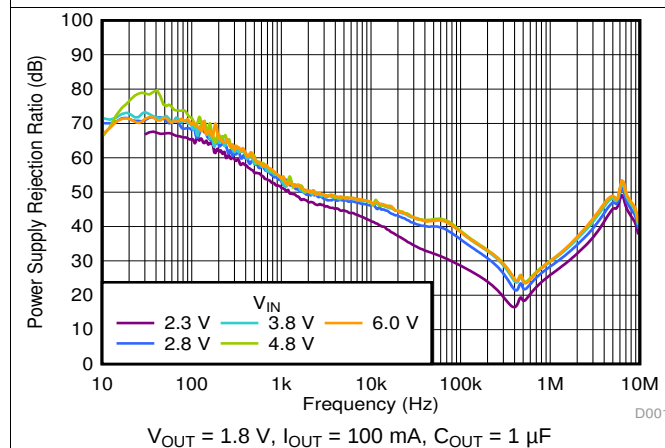


图 45. PSRR vs Frequency and  $V_{IN}$

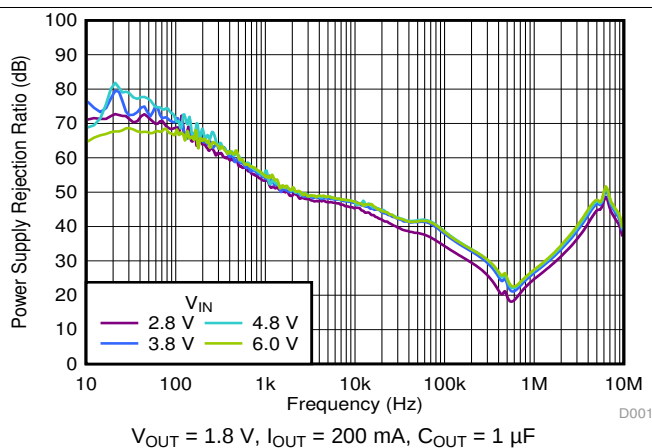


图 46. PSRR vs Frequency and  $V_{IN}$

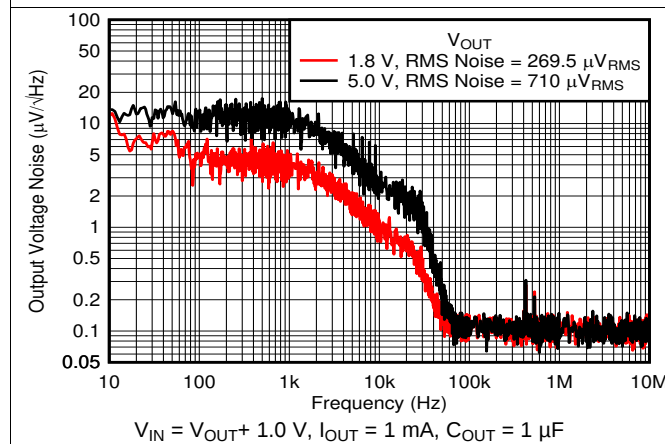


图 47. Output Noise vs Frequency and  $V_{OUT}$

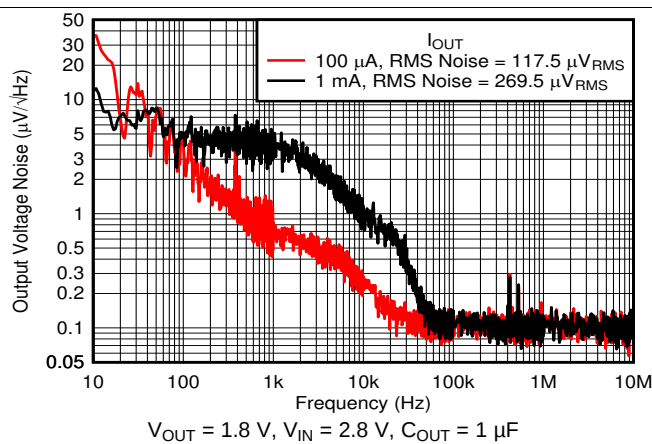
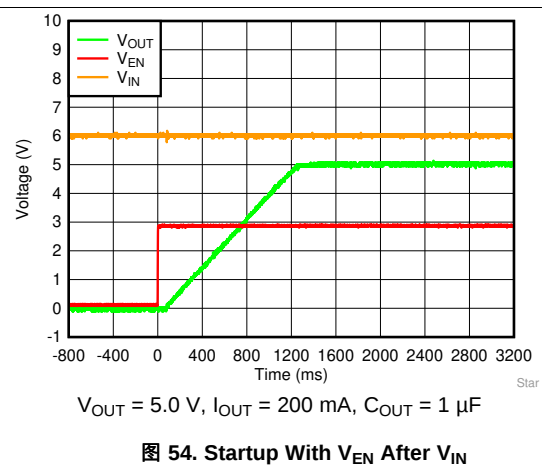
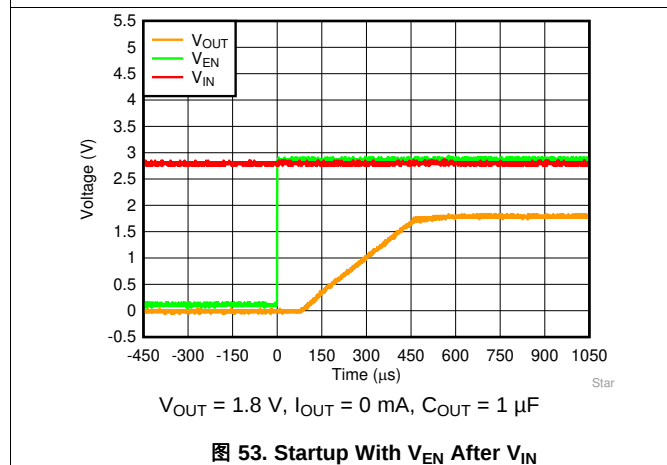
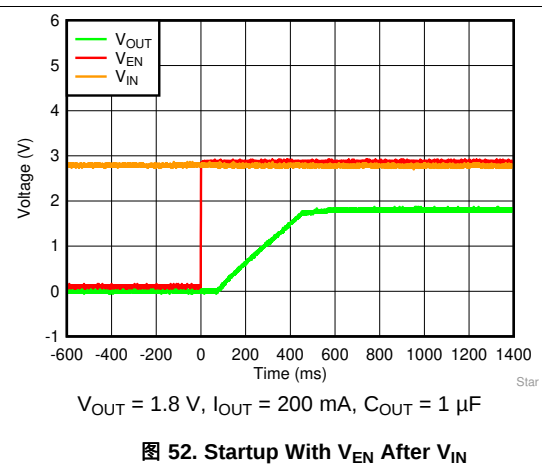
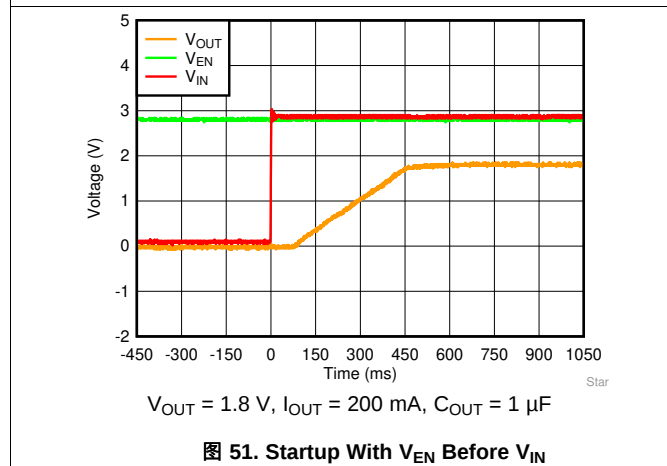
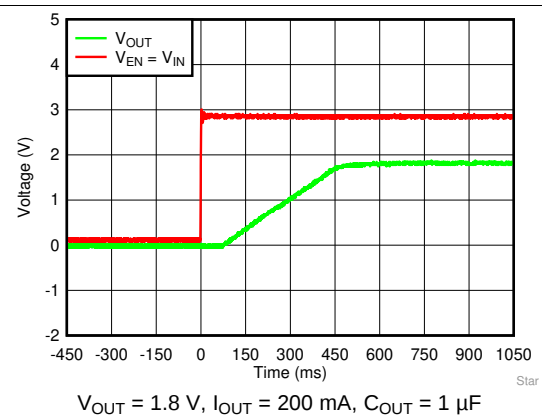
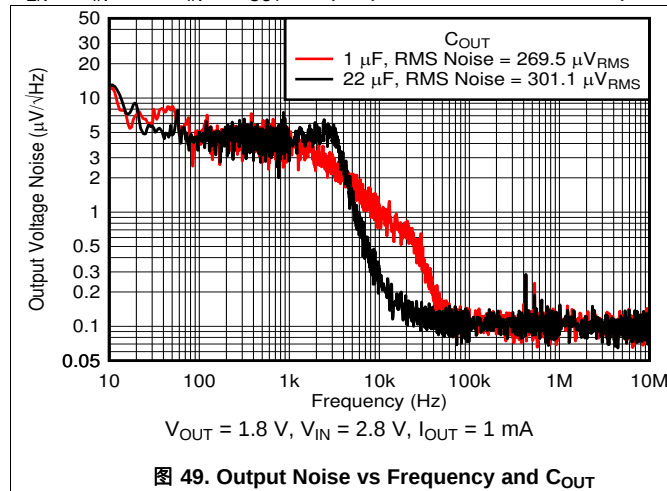


图 48. Output Noise vs Frequency and  $I_{OUT}$

## Typical Characteristics (接下页)

at operating temperature range ( $T_J = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ ),  $V_{IN} = V_{OUT(nom)} + 0.5\text{ V}$  or  $2.0\text{ V}$  (whichever is greater),  $I_{OUT} = 1\text{ mA}$ ,  $V_{EN} = V_{IN}$ , and  $C_{IN} = C_{OUT} = 1\text{ }\mu\text{F}$  (unless otherwise noted)



## Typical Characteristics (接下页)

at operating temperature range ( $T_J = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ ),  $V_{IN} = V_{OUT(nom)} + 0.5\text{ V}$  or  $2.0\text{ V}$  (whichever is greater),  $I_{OUT} = 1\text{ mA}$ ,  $V_{EN} = V_{IN}$ , and  $C_{IN} = C_{OUT} = 1\text{ }\mu\text{F}$  (unless otherwise noted)

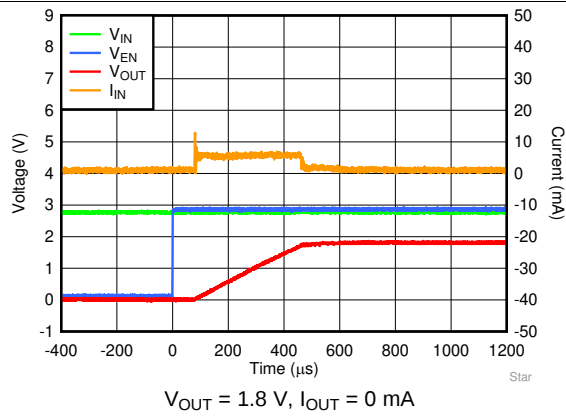


图 55. Startup Inrush Current With  $C_{OUT} = 1\text{ }\mu\text{F}$

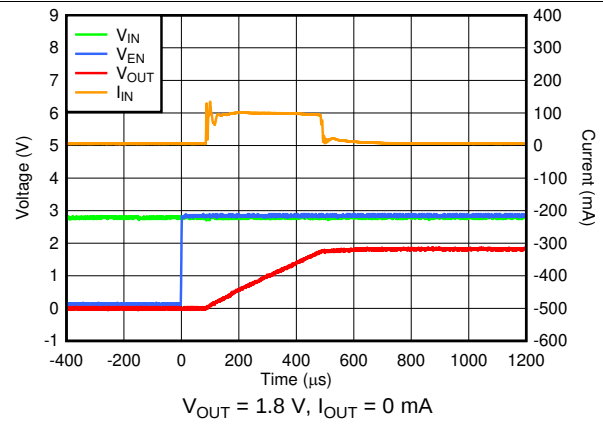


图 56. Startup Inrush Current With  $C_{OUT} = 22\text{ }\mu\text{F}$

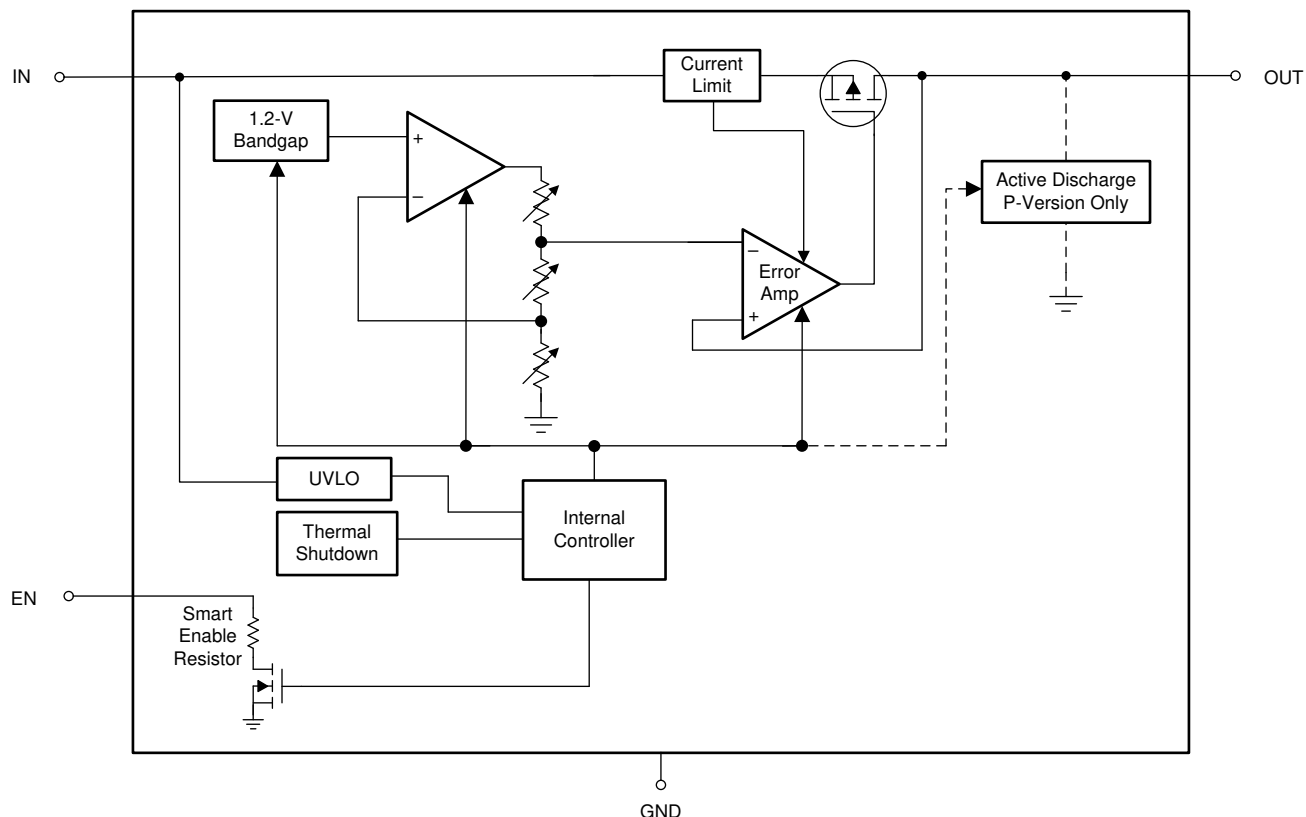
## 7 Detailed Description

### 7.1 Overview

The TPS7A02 is a ultra-low  $I_Q$  linear voltage regulator that is optimized for excellent transient performance. These characteristics make the device ideal for most battery-powered applications.

This low-dropout linear regulator (LDO) offers active discharge, foldback current limit, shutdown, and thermal protection capability.

### 7.2 Functional Block Diagram



## 7.3 Feature Description

### 7.3.1 Excellent Transient Response

The TPS7A02 includes several innovative circuits to ensure excellent transient response. Dynamic biasing increases the  $I_Q$  for a short duration during transients to extend the closed-loop bandwidth and improve the output response time to transients.

Adaptive biasing increases the  $I_Q$  as the DC load current increases, extending the bandwidth of the loop. The response time across the output voltage range is constant because a buffered reference topology is used, which keeps the control loop in unity gain at any output voltage.

These features give the device a wide loop bandwidth during transients that ensures excellent transient response while maintaining low  $I_Q$  in steady-state conditions.

### 7.3.2 Active Discharge (P-Version Only)

The device has an internal pulldown MOSFET that connects a  $R_{PULLDOWN}$  resistor to ground when the device is disabled to actively discharge the output voltage. The active discharge circuit is activated by the enable pin or by the undervoltage lockout (UVLO).

Do not rely on the active discharge circuit for discharging a large amount of output capacitance after the input supply has collapsed because reverse current can possibly flow from the output to the input. This reverse current flow can cause damage to the device. Limit reverse current to no more than 5% of the device rated current for a short period of time.

### 7.3.3 Low $I_Q$ in Dropout

In most LDOs the  $I_Q$  significantly increases when the device is placed into dropout, which is especially true for low  $I_Q$  LDOs. The TPS7A02 helps to reduce the battery discharge by detecting when the device is operating in dropout conditions and maintaining a low  $I_Q$ .

### 7.3.4 Smart Enable

The enable pin for the device is an active-high pin. The output voltage is enabled when the voltage of the enable pin is greater than the high-level input voltage of the EN pin and disabled with the enable pin voltage is less than the low-level input voltage of the EN pin. If independent control of the output voltage is not needed, connect the enable pin to the input of the device.

This device has a smart enable circuit to reduce quiescent current. When the voltage on the enable pin is driven above  $V_{EN(HI)}$ , as listed in the *Electrical Characteristics* table, the device is enabled and the smart enable internal pulldown resistor ( $R_{EN(PULLDOWN)}$ ) is disconnected. When the enable pin is floating, the  $R_{EN(PULLDOWN)}$  is connected and pulls the enable pin low to disable the device. The  $R_{EN(PULLDOWN)}$  value is listed in the *Electrical Characteristics* table.

This device has an internal pulldown circuit that activates when the device is disabled to actively discharge the output voltage.

### 7.3.5 Dropout Voltage

Dropout voltage ( $V_{DO}$ ) is defined as the input voltage minus the output voltage ( $V_{IN} - V_{OUT}$ ) at the rated output current ( $I_{RATED}$ ), where the pass transistor is fully on.  $I_{RATED}$  is the maximum  $I_{OUT}$  listed in the *Recommended Operating Conditions* table. The pass transistor is in the ohmic or triode region of operation, and acts as a switch. The dropout voltage indirectly specifies a minimum input voltage greater than the nominal programmed output voltage at which the output voltage is expected to stay in regulation. If the input voltage falls to less than the nominal output regulation, then the output voltage falls as well.

For a CMOS regulator, the dropout voltage is determined by the drain-source on-state resistance ( $R_{DS(ON)}$ ) of the pass transistor. Therefore, if the linear regulator operates at less than the rated current, the dropout voltage for that current scales accordingly. Use [Equation 1](#) to calculate the  $R_{DS(ON)}$  of the device.

$$R_{DS(ON)} = \frac{V_{DO}}{I_{RATED}} \quad (1)$$

## Feature Description (continued)

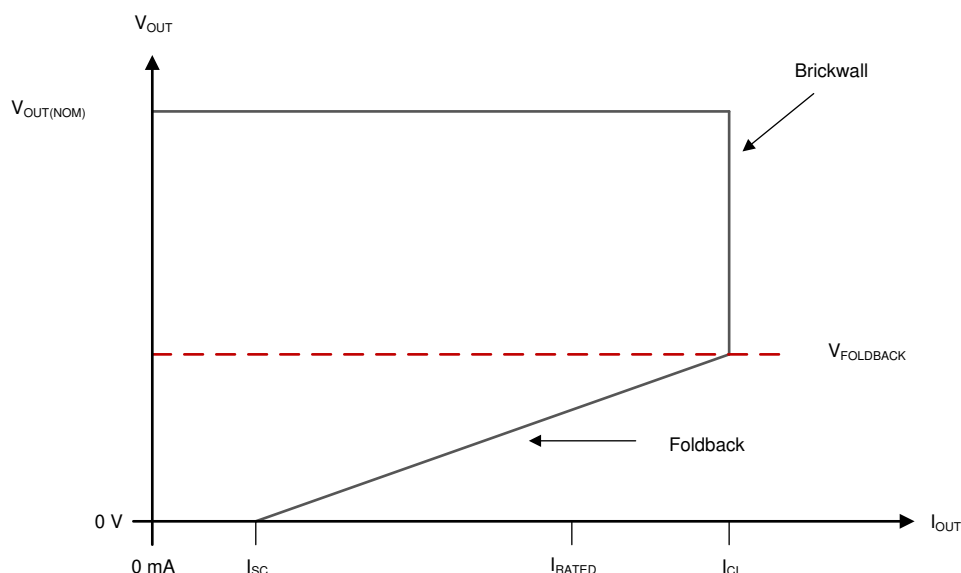
### 7.3.6 Foldback Current Limit

The device has an internal current limit circuit that protects the regulator during transient high-load current faults or shorting events. The current limit is a hybrid brickwall-foldback scheme. The current limit transitions from a brickwall scheme to a foldback scheme at the foldback voltage ( $V_{FOLDBACK}$ ). In a high-load current fault with the output voltage above  $V_{FOLDBACK}$ , the brickwall scheme limits the output current to the current limit ( $I_{CL}$ ). When the voltage drops below  $V_{FOLDBACK}$ , a foldback current limit activates that scales back the current as the output voltage approaches GND. When the output is shorted, the device supplies a typical current called the short-circuit current limit ( $I_{SC}$ ).  $I_{CL}$  and  $I_{SC}$  are listed in the *Electrical Characteristics* table.

For this device,  $V_{FOLDBACK} = 0.5\text{ V}$ .

The output voltage is not regulated when the device is in current limit. When a current limit event occurs, the device begins to heat up because of the increase in power dissipation. When the device is in brickwall current limit, the pass transistor dissipates power  $[(V_{IN} - V_{OUT}) \times I_{CL}]$ . When the device output is shorted and the output is below  $V_{FOLDBACK}$ , the pass transistor dissipates power  $[(V_{IN} - V_{OUT}) \times I_{SC}]$ . If thermal shutdown is triggered, the device turns off. After the device cools down, the internal thermal shutdown circuit turns the device back on. If the output current fault condition continues, the device cycles between current limit and thermal shutdown. For more information on current limits, see the [Know Your Limits application report](#).

Figure 57 shows a diagram of the foldback current limit.



**Figure 57. Foldback Current Limit**

### 7.3.7 Undervoltage Lockout (UVLO)

The device has an independent undervoltage lockout (UVLO) circuit that monitors the input voltage, allowing a controlled and consistent turn on and off of the output voltage. To prevent the device from turning off if the input drops during turn on, the UVLO has hysteresis as specified in the *Electrical Characteristics* table.

### 7.3.8 Thermal Shutdown

The device contains a thermal shutdown protection circuit to disable the device when the junction temperature ( $T_J$ ) of the pass transistor rises to  $T_{SD(shutdown)}$  (typical). Thermal shutdown hysteresis assures that the device resets (turns on) when the temperature falls to  $T_{SD(reset)}$  (typical).

## Feature Description (continued)

The thermal time-constant of the semiconductor die is fairly short, thus the device may cycle on and off when thermal shutdown is reached until power dissipation is reduced. Power dissipation during startup can be high from large  $V_{IN} - V_{OUT}$  voltage drops across the device or from high inrush currents charging large output capacitors. Under some conditions, the thermal shutdown protection disables the device before startup completes.

For reliable operation, limit the junction temperature to the maximum listed in the *Recommended Operating Conditions* table. Operation above this maximum temperature causes the device to exceed its operational specifications. Although the internal protection circuitry of the device is designed to protect against thermal overall conditions, this circuitry is not intended to replace proper heat sinking. Continuously running the device into thermal shutdown or above the maximum recommended junction temperature reduces long-term reliability.

## 7.4 Device Functional Modes

### 7.4.1 Device Functional Mode Comparison

The *Device Functional Mode Comparison* table shows the conditions that lead to the different modes of operation. See the *Electrical Characteristics* table for parameter values.

**Table 1. Device Functional Mode Comparison**

| OPERATING MODE                                          | PARAMETER                                                   |                        |                          |                          |
|---------------------------------------------------------|-------------------------------------------------------------|------------------------|--------------------------|--------------------------|
|                                                         | $V_{IN}$                                                    | $V_{EN}$               | $I_{OUT}$                | $T_J$                    |
| Normal operation                                        | $V_{IN} > V_{OUT(nom)} + V_{DO}$ and $V_{IN} > V_{IN(min)}$ | $V_{EN} > V_{EN(HI)}$  | $I_{OUT} < I_{OUT(max)}$ | $T_J < T_{SD(shutdown)}$ |
| Dropout operation                                       | $V_{IN(min)} < V_{IN} < V_{OUT(nom)} + V_{DO}$              | $V_{EN} > V_{EN(HI)}$  | $I_{OUT} < I_{OUT(max)}$ | $T_J < T_{SD(shutdown)}$ |
| Disabled<br>(any true condition<br>disables the device) | $V_{IN} < V_{UVLO}$                                         | $V_{EN} < V_{EN(LOW)}$ | Not applicable           | $T_J > T_{SD(shutdown)}$ |

### 7.4.2 Normal Operation

The device regulates to the nominal output voltage when the following conditions are met:

- The input voltage is greater than the nominal output voltage plus the dropout voltage ( $V_{OUT(nom)} + V_{DO}$ )
- The output current is less than the current limit ( $I_{OUT} < I_{CL}$ )
- The device junction temperature is less than the thermal shutdown temperature ( $T_J < T_{SD}$ )
- The enable voltage has previously exceeded the enable rising threshold voltage and has not yet decreased to less than the enable falling threshold

### 7.4.3 Dropout Operation

If the input voltage is lower than the nominal output voltage plus the specified dropout voltage, but all other conditions are met for normal operation, the device operates in dropout mode. In this mode, the output voltage tracks the input voltage. During this mode, the transient performance of the device becomes significantly degraded because the pass transistor is in the ohmic or triode region, and acts as a switch. Line or load transients in dropout can result in large output-voltage deviations.

When the device is in a steady dropout state (defined as when the device is in dropout,  $V_{IN} < V_{OUT(NOM)} + V_{DO}$ , directly after being in a normal regulation state, but *not* during startup), the pass transistor is driven into the ohmic or triode region. When the input voltage returns to a value greater than or equal to the nominal output voltage plus the dropout voltage ( $V_{OUT(NOM)} + V_{DO}$ ), the output voltage can overshoot for a short period of time while the device pulls the pass transistor back into the linear region.

### 7.4.4 Disabled

The output of the device can be shutdown by forcing the voltage of the enable pin to less than the maximum EN pin low-level input voltage (see the *Electrical Characteristics* table). When disabled, the pass transistor is turned off, internal circuits are shutdown, and the output voltage is actively discharged to ground by an internal discharge circuit from the output to ground.

## 8 Application and Implementation

### 注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 8.1 Application Information

#### 8.1.1 Recommended Capacitor Types

The device is designed to be stable using low equivalent series resistance (ESR) ceramic capacitors at the input and output. Multilayer ceramic capacitors have become the industry standard for these types of applications and are recommended, but must be used with good judgment. Ceramic capacitors that employ X7R-, X5R-, and C0G-rated dielectric materials provide relatively good capacitive stability across temperature, whereas the use of Y5V-rated capacitors is discouraged because of large variations in capacitance.

Regardless of the ceramic capacitor type selected, the effective capacitance varies with operating voltage and temperature. As a rule of thumb, expect the effective capacitance to decrease by as much as 50%. The input and output capacitors recommended in the *Recommended Operating Conditions* table account for an effective capacitance of approximately 50% of the nominal value.

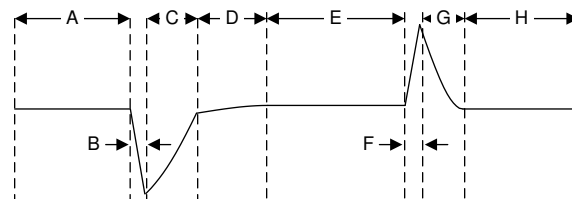
#### 8.1.2 Input and Output Capacitor Requirements

Although an input capacitor is not required for stability, good analog design practice is to connect a capacitor from IN to GND. This capacitor counteracts reactive input sources and improves transient response, input ripple, and PSRR. An input capacitor is recommended if the source impedance is more than 0.5  $\Omega$ . A higher value capacitor may be necessary if large, fast rise-time load or line transients are anticipated or if the device is located several inches from the input power source.

Dynamic performance of the device is improved with the use of an output capacitor. Use an output capacitor within the range specified in the *Recommended Operating Conditions* table for stability.

#### 8.1.3 Load Transient Response

The load-step transient response is the output voltage response by the LDO to a step in load current, whereby output voltage regulation is maintained. There are two key transitions during a load transient response: the transition from a light to a heavy load and the transition from a heavy to a light load. The regions shown in [图 58](#) are broken down as follows. Regions A, E, and H are where the output voltage is in steady-state.



**图 58. Load Transient Waveform**

During transitions from a light load to a heavy load, the:

- Initial voltage dip is a result of the depletion of the output capacitor charge and parasitic impedance to the output capacitor (region B)
- Recovery from the dip results from the LDO increasing its sourcing current, and leads to output voltage regulation (region C)

## Application Information (接下页)

During transitions from a heavy load to a light load, the:

- Initial voltage rise results from the LDO sourcing a large current, and leads to the output capacitor charge to increase (region F)
- Recovery from the rise results from the LDO decreasing its sourcing current in combination with the load discharging the output capacitor (region G)

A larger output capacitance reduces the peaks during a load transient but slows down the response time of the device. A larger DC load also reduces the peaks because the amplitude of the transition is lowered and a higher current discharge path is provided for the output capacitor.

### 8.1.4 Undervoltage Lockout (UVLO) Operation

The UVLO circuit ensures that the device stays disabled before its input supply reaches the minimum operational voltage range, and ensures that the device shuts down when the input supply collapses. 图 59 shows the UVLO circuit response to various input voltage events. The diagram can be separated into the following parts:

- Region A: The device does not start until the input reaches the UVLO rising threshold.
- Region B: Normal operation, regulating device.
- Region C: Brownout event above the UVLO falling threshold (UVLO rising threshold – UVLO hysteresis). The output may fall out of regulation but the device remains enabled.
- Region D: Normal operation, regulating device.
- Region E: Brownout event below the UVLO falling threshold. The device is disabled in most cases and the output falls because of the load and active discharge circuit. The device is reenabled when the UVLO rising threshold is reached by the input voltage and a normal start-up follows.
- Region F: Normal operation followed by the input falling to the UVLO falling threshold.
- Region G: The device is disabled when the input voltage falls below the UVLO falling threshold to 0 V. The output falls because of the load and active discharge circuit.

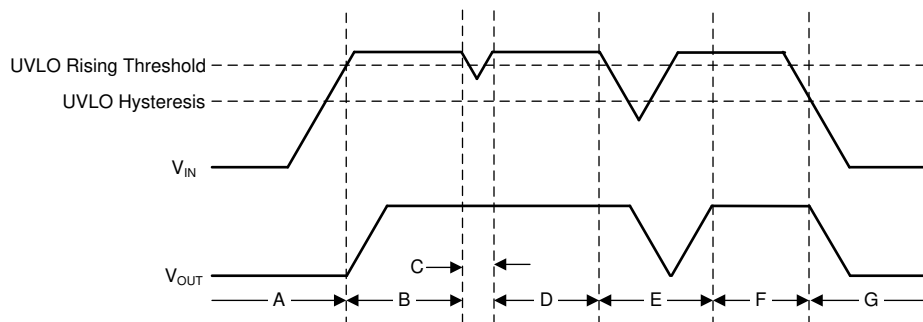


图 59. Typical UVLO Operation

### 8.1.5 Power Dissipation ( $P_D$ )

Circuit reliability demands that proper consideration be given to device power dissipation, location of the circuit on the printed circuit board (PCB), and correct sizing of the thermal plane. The PCB area around the regulator must be as free as possible of other heat-generating devices that cause added thermal stresses.

As a first-order approximation, power dissipation in the regulator depends on the input-to-output voltage difference and load conditions. Use 公式 2 to approximate  $P_D$ :

$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT} \quad (2)$$

Power dissipation can be minimized, and thus greater efficiency achieved, by proper selection of the system voltage rails. Proper selection allows the minimum input-to-output voltage differential to be obtained. The low dropout of the TPS7A02 allows for maximum efficiency across a wide range of output voltages.

The main heat conduction path for the device is through the thermal pad on the package. As such, the thermal pad must be soldered to a copper pad area under the device. This pad area contains an array of plated vias that conduct heat to any inner plane areas or to a bottom-side copper plane.

## Application Information (接下页)

The maximum power dissipation determines the maximum allowable junction temperature ( $T_J$ ) for the device. According to 公式 3, power dissipation and junction temperature are most often related by the junction-to-ambient thermal resistance ( $R_{\theta JA}$ ) of the combined PCB and device package and the temperature of the ambient air ( $T_A$ ). 公式 4 rearranges 公式 3 for output current.

$$T_J = T_A + (R_{\theta JA} \times P_D) \quad (3)$$

$$I_{OUT} = (T_J - T_A) / [R_{\theta JA} \times (V_{IN} - V_{OUT})] \quad (4)$$

Unfortunately, this thermal resistance ( $R_{\theta JA}$ ) is highly dependent on the heat-spreading capability built into the particular PCB design, and therefore varies according to the total copper area, copper weight, and location of the planes. The  $R_{\theta JA}$  recorded in the [Thermal Information](#) table is determined by the JEDEC standard, PCB, and copper-spreading area, and is only used as a relative measure of package thermal performance. For a well-designed thermal layout,  $R_{\theta JA}$  is actually the sum of the X2SON package junction-to-case (bottom) thermal resistance ( $R_{\theta JC(bot)}$ ) plus the thermal resistance contribution by the PCB copper.

### 8.1.5.1 Estimating Junction Temperature

The JEDEC standard now recommends the use of psi ( $\Psi$ ) thermal metrics to estimate the junction temperatures of the LDO when in-circuit on a typical PCB board application. These metrics are not strictly speaking thermal resistances, but rather offer practical and relative means of estimating junction temperatures. These psi metrics are determined to be significantly independent of the copper-spreading area. The key thermal metrics ( $\Psi_{JT}$  and  $\Psi_{JB}$ ) are used in accordance with 公式 5 and are given in the [Thermal Information](#) table.

$$\Psi_{JT} : T_J = T_T + \Psi_{JT} \times P_D \text{ and } \Psi_{JB} : T_J = T_B + \Psi_{JB} \times P_D$$

where:

- $P_D$  is the power dissipated as explained in 公式 2
  - $T_T$  is the temperature at the center-top of the device package, and
  - $T_B$  is the PCB surface temperature measured 1 mm from the device package and centered on the package edge
- (5)

### 8.1.5.2 Recommended Area for Continuous Operation

The operational area of an LDO is limited by the dropout voltage, output current, junction temperature, and input voltage. The recommended area for continuous operation for a linear regulator is given in 图 60 and can be separated into the following parts:

- Dropout voltage limits the minimum differential voltage between the input and the output ( $V_{IN} - V_{OUT}$ ) at a given output current level. See the [Dropout Operation](#) section for more details.
- The rated output currents limits the maximum recommended output current level. Exceeding this rating causes the device to fall out of specification.
- The rated junction temperature limits the maximum junction temperature of the device. Exceeding this rating causes the device to fall out of specification and reduces long-term reliability.
  - The shape of the slope is given by 公式 4. The slope is nonlinear because the maximum rated junction temperature of the LDO is controlled by the power dissipation across the LDO; thus when  $V_{IN} - V_{OUT}$  increases the output current must decrease.
- The rated input voltage range governs both the minimum and maximum of  $V_{IN} - V_{OUT}$ .

## Application Information (接下页)

图 60 shows the recommended area of operation for this device on a JEDEC-standard high-K board with a  $R_{\theta JA}$  as given in the [Thermal Information](#) table.

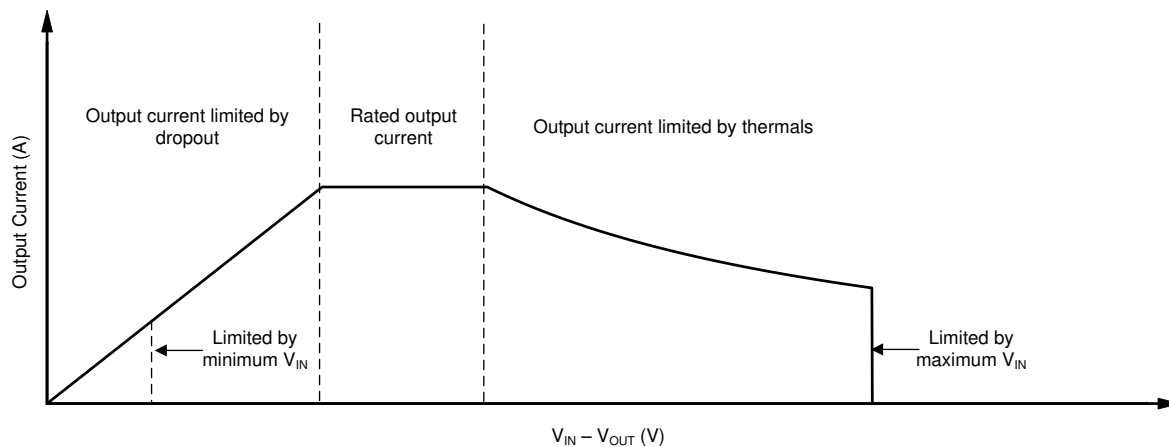


图 60. Region Description of Continuous Operation Regime

## 8.2 Typical Application

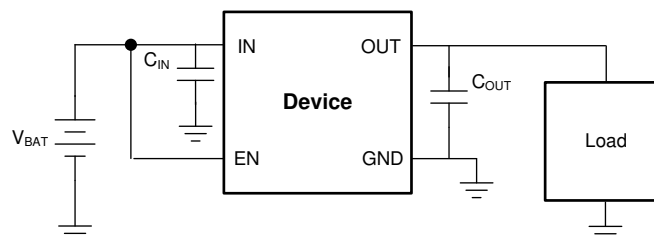


图 61. Operation From a Battery Input Supply

### 8.2.1 Design Requirements

表 2. Design Parameters

| PARAMETER                   | DESIGN REQUIREMENT                   |
|-----------------------------|--------------------------------------|
| Input voltage               | 1.8 V to 3.0 V (two 1.5-V batteries) |
| Output voltage              | 1.0 V, $\pm 1\%$                     |
| Input current               | 200 mA, maximum                      |
| Output load                 | 10-mA DC                             |
| Maximum ambient temperature | 70°C                                 |

### 8.2.2 Detailed Design Procedure

For this design example, the 1.0-V, fixed-version TPS7A0210 is selected. A dual AA Alkaline battery was used, thus a 1.0- $\mu\text{F}$  input capacitor is recommended to minimize transient currents drawn from the battery. A 1.0- $\mu\text{F}$  output capacitor is also recommended for excellent load transient response. The dropout voltage ( $V_{DO}$ ) is kept within the TPS7A02 dropout voltage specification for the 1.0-V output voltage option to keep the device in regulation under all load and temperature conditions for this design. Use the recommend 1- $\mu\text{F}$  input and output capacitor because the input source has a high equivalent series resistor (ESR) of 600 m $\Omega$  (typ). The very small ground current consumed by the regulator maintains a high current efficiency as compared to the load current consumed by the system, as shown in 图 62 which allows for long battery life. 公式 6 can be used to calculate the current efficiency ( $I_{\eta}$ ) of this system.

$$I_{\eta}(\%) = I_{OUT} / (I_{OUT} + I_Q) \times 100 \quad (6)$$

### 8.2.3 Application Curve

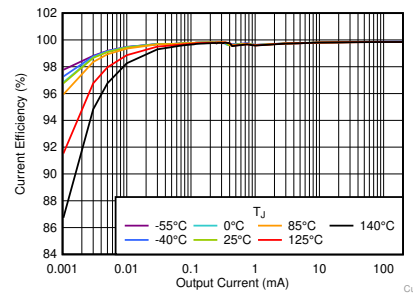


图 62. Current Efficiency vs  $I_{OUT}$  and Temperature

## 9 Power Supply Recommendations

This device is designed to operate from an input supply voltage range of 1.5 V to 6.0 V. The input supply must be well regulated and free of spurious noise. To ensure that the output voltage is well regulated and dynamic performance is optimum, the input supply must be at least  $V_{OUT(nom)} + 0.5$  V. TI highly recommends using a 1- $\mu$ F or greater input capacitor to reduce the impedance of the input supply, especially during transients.

## 10 Layout

### 10.1 Layout Guidelines

- Place input and output capacitors as close to the device as possible.
- Use copper planes for device connections to optimize thermal performance.
- Place thermal vias around the device to distribute the heat.
- Do not place a thermal via directly beneath the thermal pad of the DQN package. A via can wick solder or solder paste away from the thermal pad joint during the soldering process, leading to a compromised solder joint on the thermal pad.

### 10.2 Layout Examples

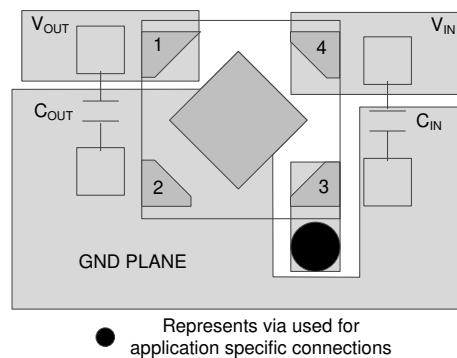


图 63. Layout Example for the DQN Package

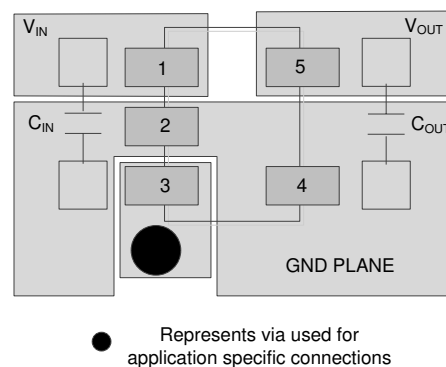


图 64. Layout Example for the DBV Package

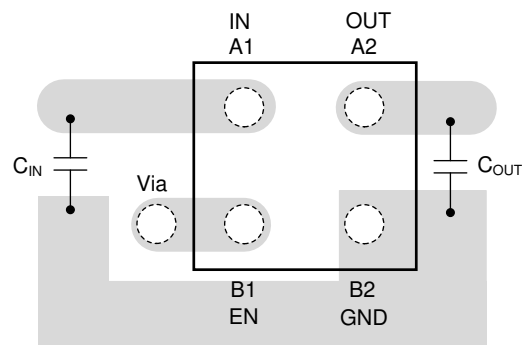


图 65. Layout Example for the YCH Package

## 11 器件和文档支持

### 11.1 器件支持

#### 11.1.1 器件命名规则

**表 3. 器件命名规则<sup>(1)(2)</sup>**

| 产品                | V <sub>OUT</sub>                                                                                                                                                                                                                              |
|-------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| TPS7A02xx(x)Pyxyz | <p><b>XX(X)</b> 是标称输出电压。对于分辨率为 100mV 的输出电压，订货编号中使用两位数字；否则，使用三位数字（例如，28 = 2.8V；125 = 1.25V）。</p> <p><b>P</b> 表示有源输出放电功能。TPS7A02 系列的所有产品在器件处于禁用状态时都可以对输出进行主动放电。</p> <p><b>YYY</b> 为封装标识符。</p> <p><b>Z</b> 为封装数量。R 表示卷（3000 片），T 表示带（250 片）。</p> |

(1) 要获得最新的封装和订货信息，请参阅本文档末尾的封装选项附录，或者访问器件产品文件夹（[www.ti.com.cn](http://www.ti.com.cn)）。

(2) 可提供 1.0V 至 3.3V 范围内的输出电压（以 50mV 为单位增量）。更多详细信息及可用性，请联系制造商。

### 11.2 接收文档更新通知

要接收文档更新通知，请导航至 [ti.com.cn](http://ti.com.cn) 上的器件产品文件夹。单击右上角的通知我进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

### 11.3 社区资源

**TI E2E™ support forums** are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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### 11.4 商标

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### 11.5 静电放电警告



ESD 可能会损坏该集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理措施和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

### 11.6 Glossary

**SLYZ022** — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 12 机械、封装和可订购信息

以下页面包含机械、封装和可订购信息。这些信息是指定器件的最新可用数据。数据如有变更，恕不另行通知，且不会对此文档进行修订。如需获取此数据表的浏览器版本，请查阅左侧的导航栏。

## PACKAGING INFORMATION

| Orderable Device | Status<br>(1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan<br>(2) | Lead finish/<br>Ball material<br>(6) | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples                 |
|------------------|---------------|--------------|--------------------|------|----------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|-------------------------|
| PTPS7A0233PYCHR  | ACTIVE        | DSBGA        | YCH                | 4    | 12000          | TBD             | Call TI                              | Call TI              | -40 to 125   |                         | <a href="#">Samples</a> |
| TPS7A0210PDQNR   | ACTIVE        | X2SON        | DQN                | 4    | 3000           | RoHS & Green    | NIPDAU   NIPDAUAG                    | Level-1-260C-UNLIM   | -40 to 125   | GH                      | <a href="#">Samples</a> |
| TPS7A0212PDBVR   | ACTIVE        | SOT-23       | DBV                | 5    | 3000           | RoHS & Green    | NIPDAU   SN                          | Level-1-260C-UNLIM   | -40 to 125   | 21GF                    | <a href="#">Samples</a> |
| TPS7A0212PYCHR   | ACTIVE        | DSBGA        | YCH                | 4    | 12000          | RoHS & Green    | SNAGCU                               | Level-1-260C-UNLIM   | -40 to 125   | A                       | <a href="#">Samples</a> |
| TPS7A0215PDBVR   | ACTIVE        | SOT-23       | DBV                | 5    | 3000           | RoHS & Green    | NIPDAU   SN                          | Level-1-260C-UNLIM   | -40 to 125   | 21KF                    | <a href="#">Samples</a> |
| TPS7A0215PDQNR   | ACTIVE        | X2SON        | DQN                | 4    | 3000           | RoHS & Green    | NIPDAU   NIPDAUAG                    | Level-1-260C-UNLIM   | -40 to 125   | F3                      | <a href="#">Samples</a> |
| TPS7A02175PYCHR  | ACTIVE        | DSBGA        | YCH                | 4    | 12000          | RoHS & Green    | SNAGCU                               | Level-1-260C-UNLIM   | -40 to 125   | S                       | <a href="#">Samples</a> |
| TPS7A02185PDQNR  | ACTIVE        | X2SON        | DQN                | 4    | 3000           | RoHS & Green    | NIPDAU   NIPDAUAG                    | Level-1-260C-UNLIM   | -40 to 125   | HO                      | <a href="#">Samples</a> |
| TPS7A0218DBVR    | ACTIVE        | SOT-23       | DBV                | 5    | 3000           | RoHS & Green    | SN                                   | Level-1-260C-UNLIM   | -40 to 125   | 2CDT                    | <a href="#">Samples</a> |
| TPS7A0218PDBVR   | ACTIVE        | SOT-23       | DBV                | 5    | 3000           | RoHS & Green    | NIPDAU   SN                          | Level-1-260C-UNLIM   | -40 to 125   | 21LF                    | <a href="#">Samples</a> |
| TPS7A0218PDQNR   | ACTIVE        | X2SON        | DQN                | 4    | 3000           | RoHS & Green    | NIPDAU   NIPDAUAG                    | Level-1-260C-UNLIM   | -40 to 125   | F4                      | <a href="#">Samples</a> |
| TPS7A0218PYCHR   | ACTIVE        | DSBGA        | YCH                | 4    | 12000          | RoHS & Green    | SNAGCU                               | Level-1-260C-UNLIM   | -40 to 125   | B                       | <a href="#">Samples</a> |
| TPS7A0220PDBVR   | ACTIVE        | SOT-23       | DBV                | 5    | 3000           | RoHS & Green    | NIPDAU   SN                          | Level-1-260C-UNLIM   | -40 to 125   | 22MT                    | <a href="#">Samples</a> |
| TPS7A0220PDQNR   | ACTIVE        | X2SON        | DQN                | 4    | 3000           | RoHS & Green    | NIPDAU   NIPDAUAG                    | Level-1-260C-UNLIM   | -40 to 125   | F5                      | <a href="#">Samples</a> |
| TPS7A0222DQNR    | ACTIVE        | X2SON        | DQN                | 4    | 3000           | RoHS & Green    | NIPDAU                               | Level-1-260C-UNLIM   | -40 to 125   | IN                      | <a href="#">Samples</a> |
| TPS7A0222PDBVR   | ACTIVE        | SOT-23       | DBV                | 5    | 3000           | RoHS & Green    | NIPDAU   SN                          | Level-1-260C-UNLIM   | -40 to 125   | 21HF                    | <a href="#">Samples</a> |
| TPS7A0222PDQNR   | ACTIVE        | X2SON        | DQN                | 4    | 3000           | RoHS & Green    | NIPDAU   NIPDAUAG                    | Level-1-260C-UNLIM   | -40 to 125   | GI                      | <a href="#">Samples</a> |
| TPS7A0223PDBVR   | ACTIVE        | SOT-23       | DBV                | 5    | 3000           | RoHS & Green    | NIPDAU   SN                          | Level-1-260C-UNLIM   | -40 to 125   | 21IF                    | <a href="#">Samples</a> |
| TPS7A0223PDQNR   | ACTIVE        | X2SON        | DQN                | 4    | 3000           | RoHS & Green    | NIPDAU   NIPDAUAG                    | Level-1-260C-UNLIM   | -40 to 125   | F6                      | <a href="#">Samples</a> |
| TPS7A0225PDBVR   | ACTIVE        | SOT-23       | DBV                | 5    | 3000           | RoHS & Green    | NIPDAU   SN                          | Level-1-260C-UNLIM   | -40 to 125   | 21DF                    | <a href="#">Samples</a> |

| Orderable Device | Status<br>(1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan<br>(2) | Lead finish/<br>Ball material<br>(6) | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples                 |
|------------------|---------------|--------------|--------------------|------|----------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|-------------------------|
| TPS7A0225PDQNR   | ACTIVE        | X2SON        | DQN                | 4    | 3000           | RoHS & Green    | NIPDAU   NIPDAUAG                    | Level-1-260C-UNLIM   | -40 to 125   | F7                      | <a href="#">Samples</a> |
| TPS7A0225PYCHR   | ACTIVE        | DSBGA        | YCH                | 4    | 12000          | RoHS & Green    | SNAGCU                               | Level-1-260C-UNLIM   | -40 to 125   | C                       | <a href="#">Samples</a> |
| TPS7A0228DBVR    | ACTIVE        | SOT-23       | DBV                | 5    | 3000           | RoHS & Green    | SN                                   | Level-1-260C-UNLIM   | -40 to 125   | 29PT                    | <a href="#">Samples</a> |
| TPS7A0228DQNR    | ACTIVE        | X2SON        | DQN                | 4    | 3000           | RoHS & Green    | NIPDAU                               | Level-1-260C-UNLIM   | -40 to 125   | IE                      | <a href="#">Samples</a> |
| TPS7A0228PDBVR   | ACTIVE        | SOT-23       | DBV                | 5    | 3000           | RoHS & Green    | NIPDAU   SN                          | Level-1-260C-UNLIM   | -40 to 125   | 21EF                    | <a href="#">Samples</a> |
| TPS7A0228PDQNR   | ACTIVE        | X2SON        | DQN                | 4    | 3000           | RoHS & Green    | NIPDAU   NIPDAUAG                    | Level-1-260C-UNLIM   | -40 to 125   | F8                      | <a href="#">Samples</a> |
| TPS7A0228PYCHR   | ACTIVE        | DSBGA        | YCH                | 4    | 12000          | RoHS & Green    | SNAGCU                               | Level-1-260C-UNLIM   | -40 to 125   | D                       | <a href="#">Samples</a> |
| TPS7A0230PDBVR   | ACTIVE        | SOT-23       | DBV                | 5    | 3000           | RoHS & Green    | NIPDAU   SN                          | Level-1-260C-UNLIM   | -40 to 125   | 21MF                    | <a href="#">Samples</a> |
| TPS7A0230PDQNR   | ACTIVE        | X2SON        | DQN                | 4    | 3000           | RoHS & Green    | NIPDAU   NIPDAUAG                    | Level-1-260C-UNLIM   | -40 to 125   | F9                      | <a href="#">Samples</a> |
| TPS7A0230PYCHR   | ACTIVE        | DSBGA        | YCH                | 4    | 12000          | RoHS & Green    | SNAGCU                               | Level-1-260C-UNLIM   | -40 to 125   | F                       | <a href="#">Samples</a> |
| TPS7A0231PDQNR   | ACTIVE        | X2SON        | DQN                | 4    | 3000           | RoHS & Green    | NIPDAU   NIPDAUAG                    | Level-1-260C-UNLIM   | -40 to 125   | GJ                      | <a href="#">Samples</a> |
| TPS7A0233DBVR    | ACTIVE        | SOT-23       | DBV                | 5    | 3000           | RoHS & Green    | SN                                   | Level-1-260C-UNLIM   | -40 to 125   | 29QT                    | <a href="#">Samples</a> |
| TPS7A0233DQNR    | ACTIVE        | X2SON        | DQN                | 4    | 3000           | RoHS & Green    | NIPDAU                               | Level-1-260C-UNLIM   | -40 to 125   | IF                      | <a href="#">Samples</a> |
| TPS7A0233PDBVR   | ACTIVE        | SOT-23       | DBV                | 5    | 3000           | RoHS & Green    | NIPDAU   SN                          | Level-1-260C-UNLIM   | -40 to 125   | 21FF                    | <a href="#">Samples</a> |
| TPS7A0233PDQNR   | ACTIVE        | X2SON        | DQN                | 4    | 3000           | RoHS & Green    | NIPDAU   NIPDAUAG                    | Level-1-260C-UNLIM   | -40 to 125   | FA                      | <a href="#">Samples</a> |
| TPS7A0233PYCHR   | ACTIVE        | DSBGA        | YCH                | 4    | 12000          | RoHS & Green    | SNAGCU                               | Level-1-260C-UNLIM   | -40 to 125   | G                       | <a href="#">Samples</a> |
| TPS7A0236PDBVR   | ACTIVE        | SOT-23       | DBV                | 5    | 3000           | RoHS & Green    | NIPDAU   SN                          | Level-1-260C-UNLIM   | -40 to 125   | (21FF, 21JF)            | <a href="#">Samples</a> |

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of  $\leq 1000$ ppm threshold. Antimony trioxide based flame retardants must also meet the  $\leq 1000$ ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

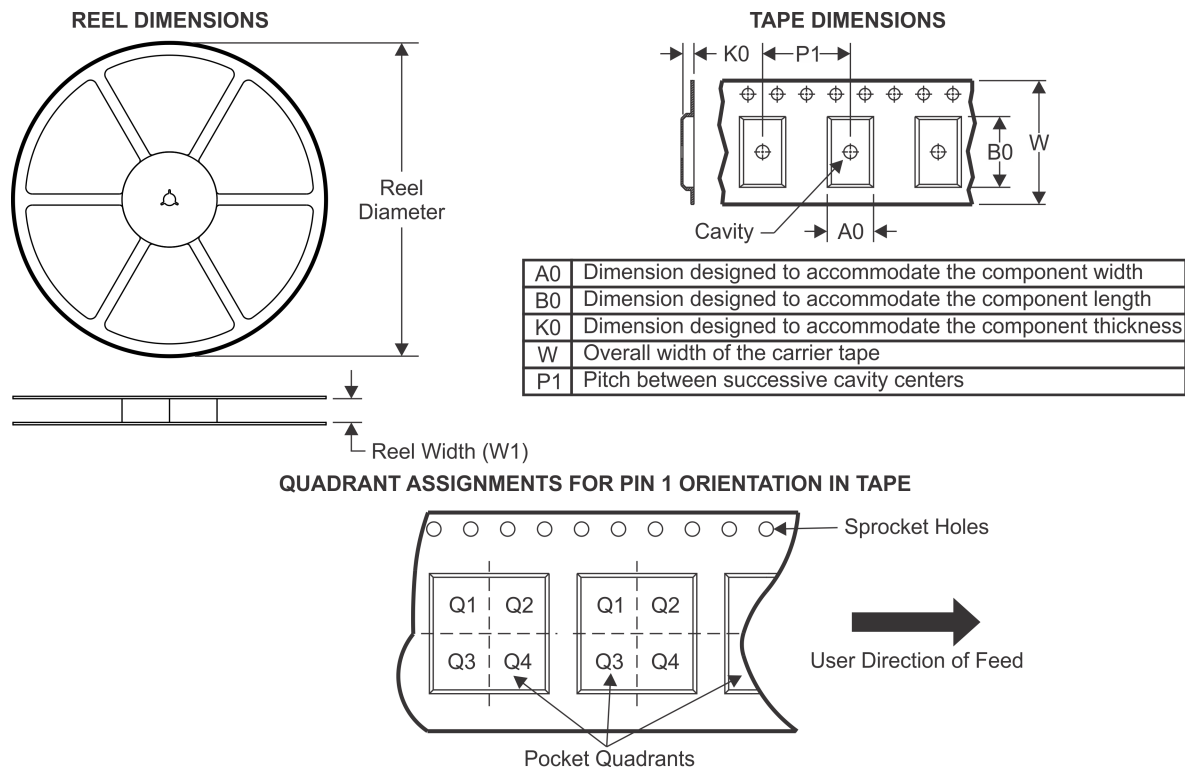
<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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## TAPE AND REEL INFORMATION

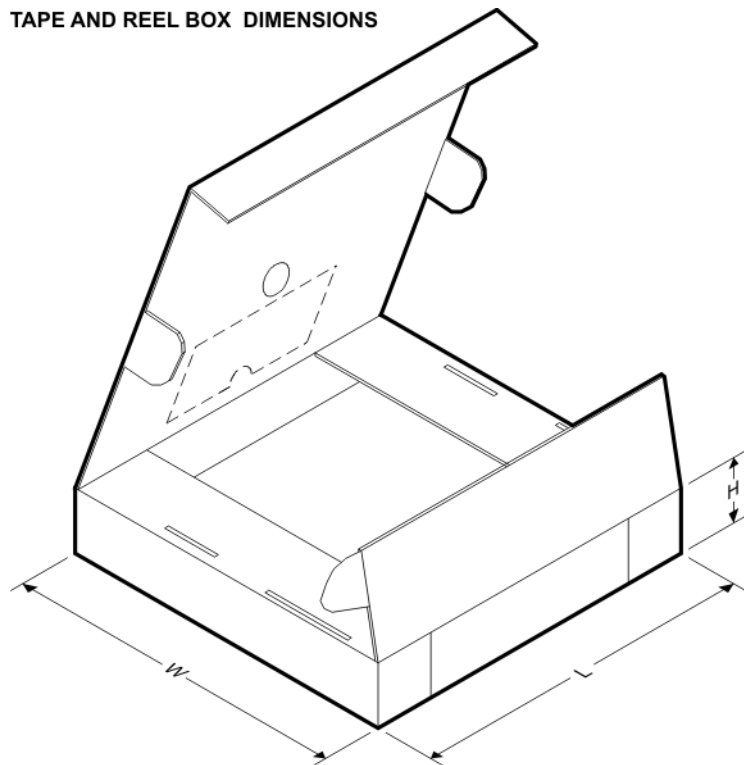


\*All dimensions are nominal

| Device          | Package Type | Package Drawing | Pins | SPQ   | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-----------------|--------------|-----------------|------|-------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TPS7A0210PDQNR  | X2SON        | DQN             | 4    | 3000  | 180.0              | 9.5                | 1.16    | 1.16    | 0.5     | 4.0     | 8.0    | Q2            |
| TPS7A0210PDQNR  | X2SON        | DQN             | 4    | 3000  | 178.0              | 8.4                | 1.13    | 1.13    | 0.53    | 4.0     | 8.0    | Q2            |
| TPS7A0212PDBVR  | SOT-23       | DBV             | 5    | 3000  | 178.0              | 9.0                | 3.3     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS7A0212PYCHR  | DSBGA        | YCH             | 4    | 12000 | 180.0              | 8.4                | 0.72    | 0.72    | 0.42    | 2.0     | 8.0    | Q1            |
| TPS7A0215PDBVR  | SOT-23       | DBV             | 5    | 3000  | 178.0              | 9.0                | 3.3     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS7A0215PDQNR  | X2SON        | DQN             | 4    | 3000  | 180.0              | 9.5                | 1.16    | 1.16    | 0.5     | 4.0     | 8.0    | Q2            |
| TPS7A0215PDQNR  | X2SON        | DQN             | 4    | 3000  | 178.0              | 8.4                | 1.13    | 1.13    | 0.53    | 4.0     | 8.0    | Q2            |
| TPS7A02175PYCHR | DSBGA        | YCH             | 4    | 12000 | 180.0              | 8.4                | 0.72    | 0.72    | 0.42    | 2.0     | 8.0    | Q1            |
| TPS7A02185PDQNR | X2SON        | DQN             | 4    | 3000  | 180.0              | 9.5                | 1.16    | 1.16    | 0.5     | 4.0     | 8.0    | Q2            |
| TPS7A02185PDQNR | X2SON        | DQN             | 4    | 3000  | 178.0              | 8.4                | 1.13    | 1.13    | 0.53    | 4.0     | 8.0    | Q2            |
| TPS7A0218DBVR   | SOT-23       | DBV             | 5    | 3000  | 178.0              | 9.0                | 3.3     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS7A0218PDBVR  | SOT-23       | DBV             | 5    | 3000  | 178.0              | 9.0                | 3.3     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS7A0218PDQNR  | X2SON        | DQN             | 4    | 3000  | 178.0              | 8.4                | 1.13    | 1.13    | 0.53    | 4.0     | 8.0    | Q2            |
| TPS7A0218PDQNR  | X2SON        | DQN             | 4    | 3000  | 180.0              | 9.5                | 1.16    | 1.16    | 0.5     | 4.0     | 8.0    | Q2            |
| TPS7A0218PYCHR  | DSBGA        | YCH             | 4    | 12000 | 180.0              | 8.4                | 0.72    | 0.72    | 0.42    | 2.0     | 8.0    | Q1            |
| TPS7A0220PDBVR  | SOT-23       | DBV             | 5    | 3000  | 178.0              | 9.0                | 3.3     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS7A0220PDQNR  | X2SON        | DQN             | 4    | 3000  | 180.0              | 9.5                | 1.16    | 1.16    | 0.5     | 4.0     | 8.0    | Q2            |
| TPS7A0220PDQNR  | X2SON        | DQN             | 4    | 3000  | 178.0              | 8.4                | 1.13    | 1.13    | 0.53    | 4.0     | 8.0    | Q2            |

| Device         | Package Type | Package Drawing | Pins | SPQ   | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|----------------|--------------|-----------------|------|-------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TPS7A0222DQNR  | X2SON        | DQN             | 4    | 3000  | 180.0              | 9.5                | 1.16    | 1.16    | 0.5     | 4.0     | 8.0    | Q2            |
| TPS7A0222PDBVR | SOT-23       | DBV             | 5    | 3000  | 178.0              | 9.0                | 3.3     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS7A0222PDQNR | X2SON        | DQN             | 4    | 3000  | 178.0              | 8.4                | 1.13    | 1.13    | 0.53    | 4.0     | 8.0    | Q2            |
| TPS7A0222PDQNR | X2SON        | DQN             | 4    | 3000  | 180.0              | 9.5                | 1.16    | 1.16    | 0.5     | 4.0     | 8.0    | Q2            |
| TPS7A0223PDBVR | SOT-23       | DBV             | 5    | 3000  | 178.0              | 9.0                | 3.3     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS7A0223PDQNR | X2SON        | DQN             | 4    | 3000  | 178.0              | 8.4                | 1.13    | 1.13    | 0.53    | 4.0     | 8.0    | Q2            |
| TPS7A0223PDQNR | X2SON        | DQN             | 4    | 3000  | 180.0              | 9.5                | 1.16    | 1.16    | 0.5     | 4.0     | 8.0    | Q2            |
| TPS7A0225PDBVR | SOT-23       | DBV             | 5    | 3000  | 178.0              | 9.0                | 3.3     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS7A0225PDBVR | SOT-23       | DBV             | 5    | 3000  | 180.0              | 8.4                | 3.2     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS7A0225PDQNR | X2SON        | DQN             | 4    | 3000  | 178.0              | 8.4                | 1.13    | 1.13    | 0.53    | 4.0     | 8.0    | Q2            |
| TPS7A0225PDQNR | X2SON        | DQN             | 4    | 3000  | 180.0              | 9.5                | 1.16    | 1.16    | 0.5     | 4.0     | 8.0    | Q2            |
| TPS7A0225PYCHR | DSBGA        | YCH             | 4    | 12000 | 180.0              | 8.4                | 0.72    | 0.72    | 0.42    | 2.0     | 8.0    | Q1            |
| TPS7A0228DBVR  | SOT-23       | DBV             | 5    | 3000  | 178.0              | 9.0                | 3.3     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS7A0228DQNR  | X2SON        | DQN             | 4    | 3000  | 180.0              | 9.5                | 1.16    | 1.16    | 0.5     | 4.0     | 8.0    | Q2            |
| TPS7A0228PDBVR | SOT-23       | DBV             | 5    | 3000  | 180.0              | 8.4                | 3.2     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS7A0228PDBVR | SOT-23       | DBV             | 5    | 3000  | 178.0              | 9.0                | 3.3     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS7A0228PDQNR | X2SON        | DQN             | 4    | 3000  | 180.0              | 9.5                | 1.16    | 1.16    | 0.5     | 4.0     | 8.0    | Q2            |
| TPS7A0228PDQNR | X2SON        | DQN             | 4    | 3000  | 178.0              | 8.4                | 1.13    | 1.13    | 0.53    | 4.0     | 8.0    | Q2            |
| TPS7A0228PYCHR | DSBGA        | YCH             | 4    | 12000 | 180.0              | 8.4                | 0.72    | 0.72    | 0.42    | 2.0     | 8.0    | Q1            |
| TPS7A0230PDBVR | SOT-23       | DBV             | 5    | 3000  | 178.0              | 9.0                | 3.3     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS7A0230PDQNR | X2SON        | DQN             | 4    | 3000  | 178.0              | 8.4                | 1.13    | 1.13    | 0.53    | 4.0     | 8.0    | Q2            |
| TPS7A0230PDQNR | X2SON        | DQN             | 4    | 3000  | 180.0              | 9.5                | 1.16    | 1.16    | 0.5     | 4.0     | 8.0    | Q2            |
| TPS7A0230PYCHR | DSBGA        | YCH             | 4    | 12000 | 180.0              | 8.4                | 0.72    | 0.72    | 0.42    | 2.0     | 8.0    | Q1            |
| TPS7A0231PDQNR | X2SON        | DQN             | 4    | 3000  | 178.0              | 8.4                | 1.13    | 1.13    | 0.53    | 4.0     | 8.0    | Q2            |
| TPS7A0231PDQNR | X2SON        | DQN             | 4    | 3000  | 180.0              | 9.5                | 1.16    | 1.16    | 0.5     | 4.0     | 8.0    | Q2            |
| TPS7A0233DBVR  | SOT-23       | DBV             | 5    | 3000  | 178.0              | 9.0                | 3.3     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS7A0233DQNR  | X2SON        | DQN             | 4    | 3000  | 180.0              | 9.5                | 1.16    | 1.16    | 0.5     | 4.0     | 8.0    | Q2            |
| TPS7A0233PDBVR | SOT-23       | DBV             | 5    | 3000  | 178.0              | 9.0                | 3.3     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS7A0233PDQNR | X2SON        | DQN             | 4    | 3000  | 180.0              | 9.5                | 1.16    | 1.16    | 0.5     | 4.0     | 8.0    | Q2            |
| TPS7A0233PDQNR | X2SON        | DQN             | 4    | 3000  | 178.0              | 8.4                | 1.13    | 1.13    | 0.53    | 4.0     | 8.0    | Q2            |
| TPS7A0233PYCHR | DSBGA        | YCH             | 4    | 12000 | 180.0              | 8.4                | 0.72    | 0.72    | 0.42    | 2.0     | 8.0    | Q1            |
| TPS7A0236PDBVR | SOT-23       | DBV             | 5    | 3000  | 178.0              | 9.0                | 3.3     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device          | Package Type | Package Drawing | Pins | SPQ   | Length (mm) | Width (mm) | Height (mm) |
|-----------------|--------------|-----------------|------|-------|-------------|------------|-------------|
| TPS7A0210PDQNR  | X2SON        | DQN             | 4    | 3000  | 184.0       | 184.0      | 19.0        |
| TPS7A0210PDQNR  | X2SON        | DQN             | 4    | 3000  | 205.0       | 200.0      | 33.0        |
| TPS7A0212PDBVR  | SOT-23       | DBV             | 5    | 3000  | 180.0       | 180.0      | 18.0        |
| TPS7A0212PYCHR  | DSBGA        | YCH             | 4    | 12000 | 182.0       | 182.0      | 20.0        |
| TPS7A0215PDBVR  | SOT-23       | DBV             | 5    | 3000  | 180.0       | 180.0      | 18.0        |
| TPS7A0215PDQNR  | X2SON        | DQN             | 4    | 3000  | 184.0       | 184.0      | 19.0        |
| TPS7A0215PDQNR  | X2SON        | DQN             | 4    | 3000  | 205.0       | 200.0      | 33.0        |
| TPS7A02175PYCHR | DSBGA        | YCH             | 4    | 12000 | 182.0       | 182.0      | 20.0        |
| TPS7A02185PDQNR | X2SON        | DQN             | 4    | 3000  | 184.0       | 184.0      | 19.0        |
| TPS7A02185PDQNR | X2SON        | DQN             | 4    | 3000  | 205.0       | 200.0      | 33.0        |
| TPS7A0218DBVR   | SOT-23       | DBV             | 5    | 3000  | 180.0       | 180.0      | 18.0        |
| TPS7A0218PDBVR  | SOT-23       | DBV             | 5    | 3000  | 180.0       | 180.0      | 18.0        |
| TPS7A0218PDQNR  | X2SON        | DQN             | 4    | 3000  | 205.0       | 200.0      | 33.0        |
| TPS7A0218PDQNR  | X2SON        | DQN             | 4    | 3000  | 184.0       | 184.0      | 19.0        |
| TPS7A0218PYCHR  | DSBGA        | YCH             | 4    | 12000 | 182.0       | 182.0      | 20.0        |
| TPS7A0220PDBVR  | SOT-23       | DBV             | 5    | 3000  | 180.0       | 180.0      | 18.0        |
| TPS7A0220PDQNR  | X2SON        | DQN             | 4    | 3000  | 184.0       | 184.0      | 19.0        |
| TPS7A0220PDQNR  | X2SON        | DQN             | 4    | 3000  | 205.0       | 200.0      | 33.0        |
| TPS7A0222DQNR   | X2SON        | DQN             | 4    | 3000  | 184.0       | 184.0      | 19.0        |
| TPS7A0222PDBVR  | SOT-23       | DBV             | 5    | 3000  | 180.0       | 180.0      | 18.0        |

| Device         | Package Type | Package Drawing | Pins | SPQ   | Length (mm) | Width (mm) | Height (mm) |
|----------------|--------------|-----------------|------|-------|-------------|------------|-------------|
| TPS7A0222PDQNR | X2SON        | DQN             | 4    | 3000  | 205.0       | 200.0      | 33.0        |
| TPS7A0222PDQNR | X2SON        | DQN             | 4    | 3000  | 184.0       | 184.0      | 19.0        |
| TPS7A0223PDBVR | SOT-23       | DBV             | 5    | 3000  | 180.0       | 180.0      | 18.0        |
| TPS7A0223PDQNR | X2SON        | DQN             | 4    | 3000  | 205.0       | 200.0      | 33.0        |
| TPS7A0223PDQNR | X2SON        | DQN             | 4    | 3000  | 184.0       | 184.0      | 19.0        |
| TPS7A0225PDBVR | SOT-23       | DBV             | 5    | 3000  | 180.0       | 180.0      | 18.0        |
| TPS7A0225PDBVR | SOT-23       | DBV             | 5    | 3000  | 210.0       | 185.0      | 35.0        |
| TPS7A0225PDQNR | X2SON        | DQN             | 4    | 3000  | 205.0       | 200.0      | 33.0        |
| TPS7A0225PDQNR | X2SON        | DQN             | 4    | 3000  | 184.0       | 184.0      | 19.0        |
| TPS7A0225PYCHR | DSBGA        | YCH             | 4    | 12000 | 182.0       | 182.0      | 20.0        |
| TPS7A0228DBVR  | SOT-23       | DBV             | 5    | 3000  | 180.0       | 180.0      | 18.0        |
| TPS7A0228DQNR  | X2SON        | DQN             | 4    | 3000  | 184.0       | 184.0      | 19.0        |
| TPS7A0228PDBVR | SOT-23       | DBV             | 5    | 3000  | 210.0       | 185.0      | 35.0        |
| TPS7A0228PDBVR | SOT-23       | DBV             | 5    | 3000  | 180.0       | 180.0      | 18.0        |
| TPS7A0228PDQNR | X2SON        | DQN             | 4    | 3000  | 184.0       | 184.0      | 19.0        |
| TPS7A0228PDQNR | X2SON        | DQN             | 4    | 3000  | 205.0       | 200.0      | 33.0        |
| TPS7A0228PYCHR | DSBGA        | YCH             | 4    | 12000 | 182.0       | 182.0      | 20.0        |
| TPS7A0230PDBVR | SOT-23       | DBV             | 5    | 3000  | 180.0       | 180.0      | 18.0        |
| TPS7A0230PDQNR | X2SON        | DQN             | 4    | 3000  | 205.0       | 200.0      | 33.0        |
| TPS7A0230PDQNR | X2SON        | DQN             | 4    | 3000  | 184.0       | 184.0      | 19.0        |
| TPS7A0230PYCHR | DSBGA        | YCH             | 4    | 12000 | 182.0       | 182.0      | 20.0        |
| TPS7A0231PDQNR | X2SON        | DQN             | 4    | 3000  | 205.0       | 200.0      | 33.0        |
| TPS7A0231PDQNR | X2SON        | DQN             | 4    | 3000  | 184.0       | 184.0      | 19.0        |
| TPS7A0233DBVR  | SOT-23       | DBV             | 5    | 3000  | 180.0       | 180.0      | 18.0        |
| TPS7A0233DQNR  | X2SON        | DQN             | 4    | 3000  | 184.0       | 184.0      | 19.0        |
| TPS7A0233PDBVR | SOT-23       | DBV             | 5    | 3000  | 180.0       | 180.0      | 18.0        |
| TPS7A0233PDQNR | X2SON        | DQN             | 4    | 3000  | 184.0       | 184.0      | 19.0        |
| TPS7A0233PDQNR | X2SON        | DQN             | 4    | 3000  | 205.0       | 200.0      | 33.0        |
| TPS7A0233PYCHR | DSBGA        | YCH             | 4    | 12000 | 182.0       | 182.0      | 20.0        |
| TPS7A0236PDBVR | SOT-23       | DBV             | 5    | 3000  | 180.0       | 180.0      | 18.0        |

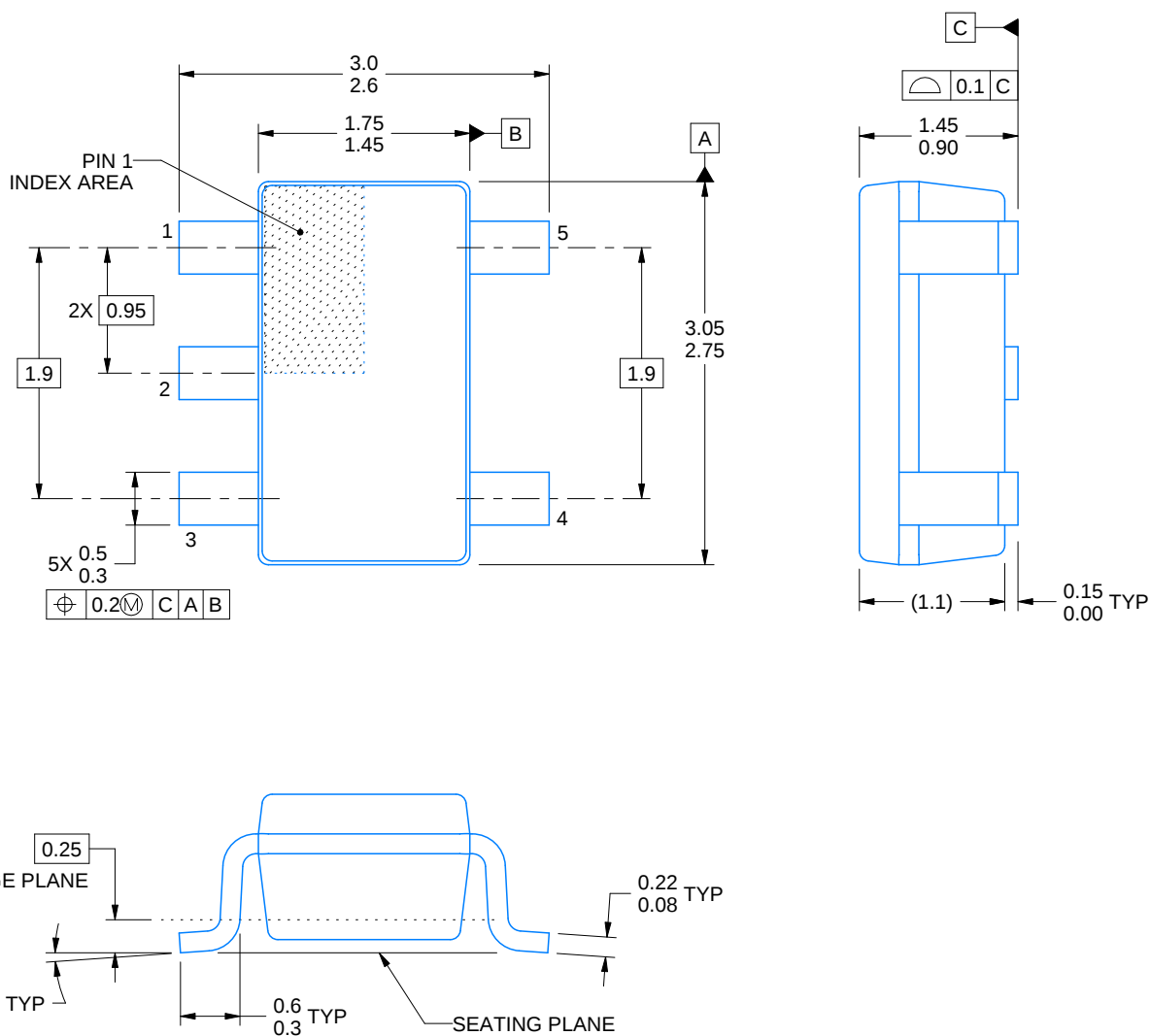


**DBV0005A**

# PACKAGE OUTLINE

**SOT-23 - 1.45 mm max height**

SMALL OUTLINE TRANSISTOR



4214839/F 06/2021

## NOTES:

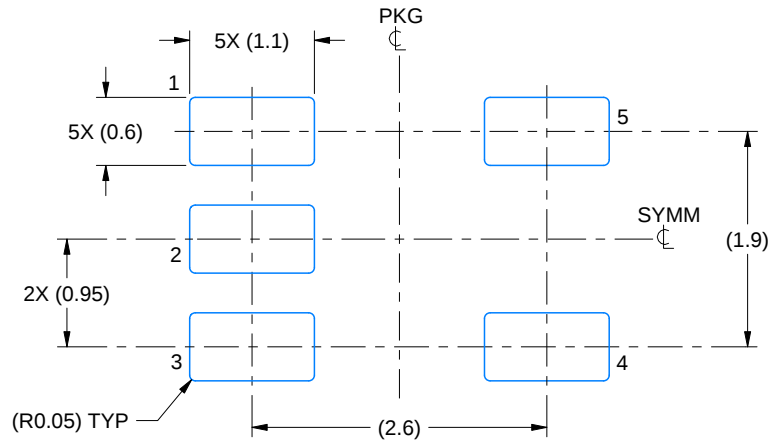
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.

# EXAMPLE BOARD LAYOUT

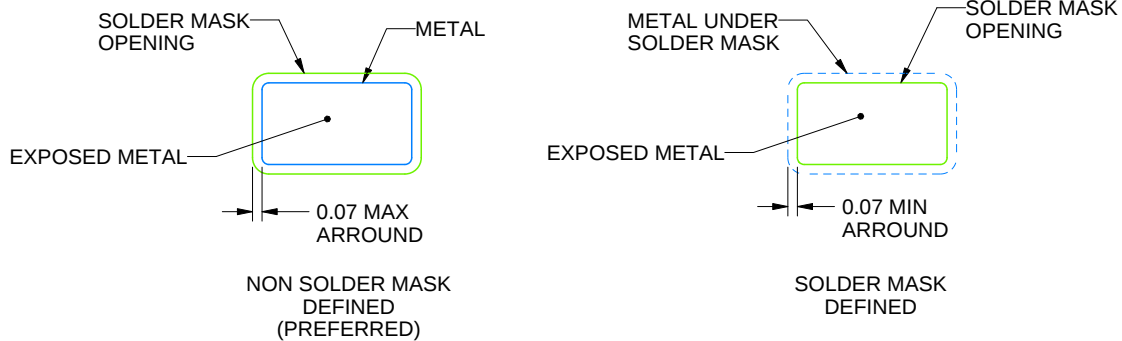
DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:15X



SOLDER MASK DETAILS

4214839/F 06/2021

NOTES: (continued)

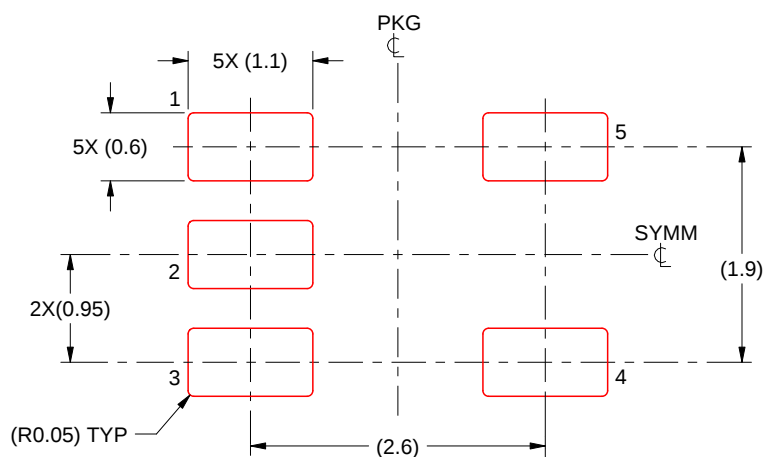
5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

## EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:15X

4214839/F 06/2021

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

**DQN 4**

## GENERIC PACKAGE VIEW

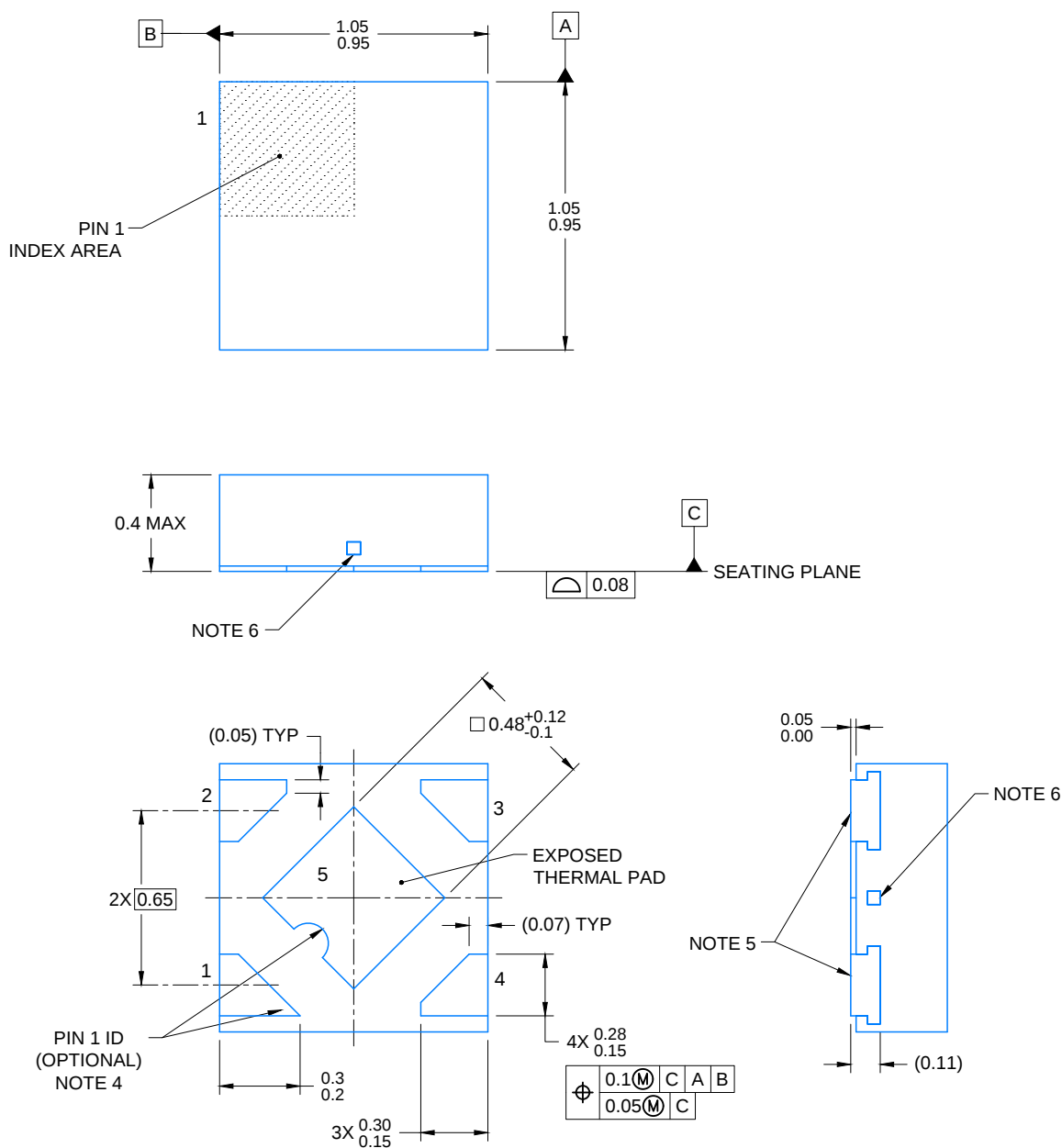
**X2SON - 0.4 mm max height**

PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.

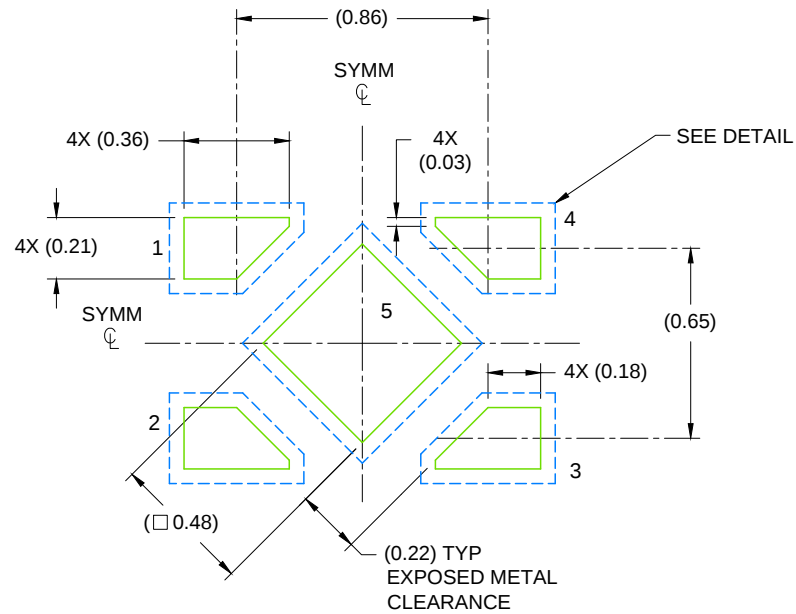
4210367/F



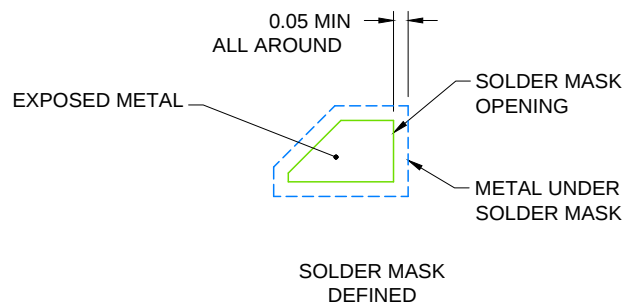
4215302/E 12/2016

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.
4. Features may not exist. Recommend use of pin 1 marking on top of package for orientation purposes.
5. Shape of exposed side leads may differ.
6. Number and location of exposed tie bars may vary.



LAND PATTERN EXAMPLE  
SCALE: 40X

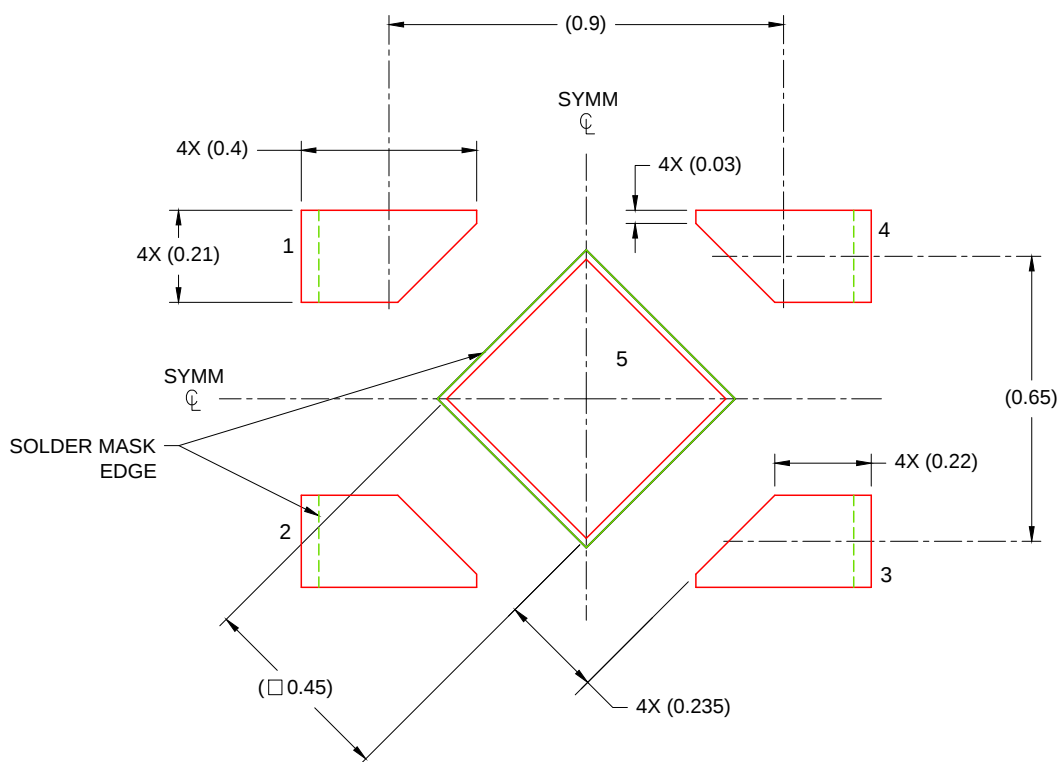


SOLDER MASK DETAIL

4215302/E 12/2016

NOTES: (continued)

7. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/sluea271](http://www.ti.com/lit/sluea271)).
8. If any vias are implemented, it is recommended that vias under paste be filled, plugged or tented.



SOLDER PASTE EXAMPLE  
 BASED ON 0.075 - 0.1mm THICK STENCIL

EXPOSED PAD  
 88% PRINTED SOLDER COVERAGE BY AREA  
 SCALE: 60X

4215302/E 12/2016

NOTES: (continued)

9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

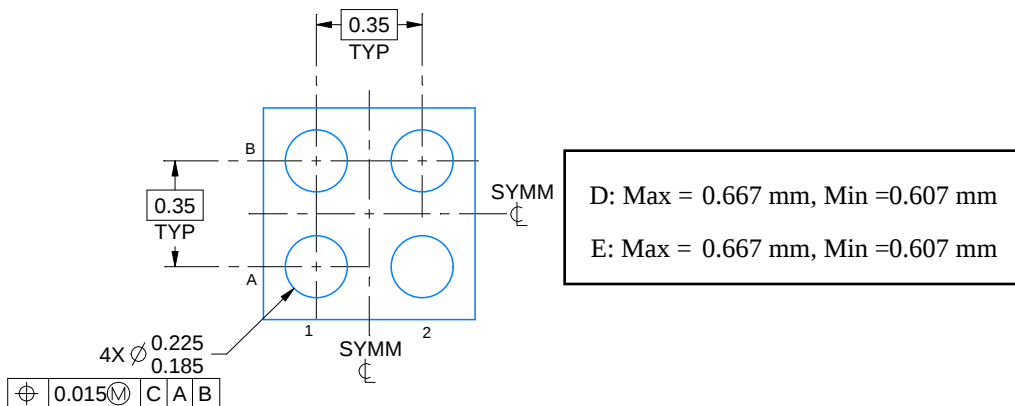
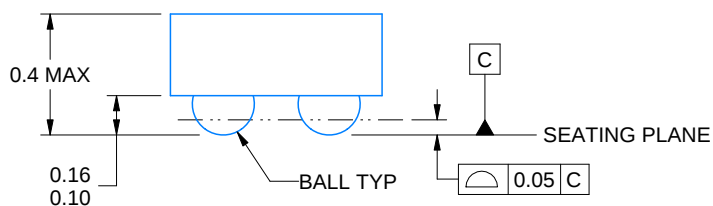
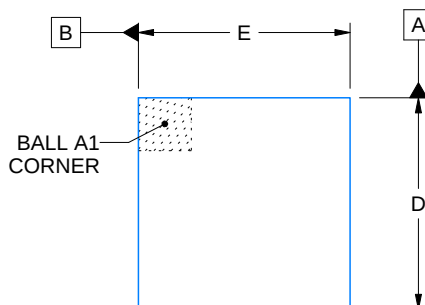
YCH0004



# PACKAGE OUTLINE

DSBGA - 0.4 mm max height

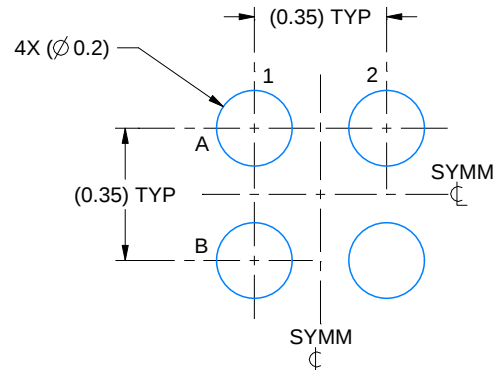
DIE SIZE BALL GRID ARRAY



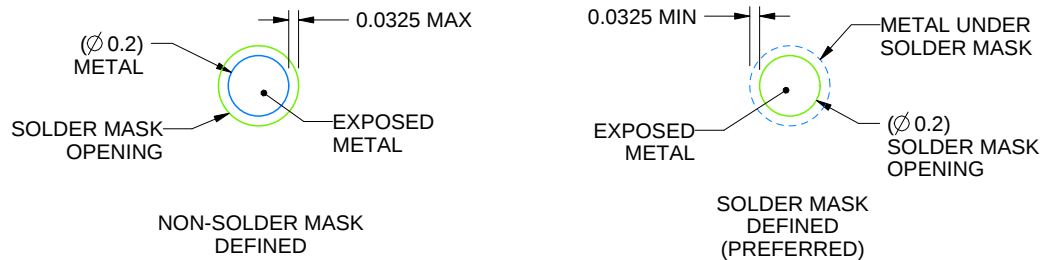
4224061/A 12/2017

## NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 50X



SOLDER MASK DETAILS  
NOT TO SCALE

4224061/A 12/2017

NOTES: (continued)

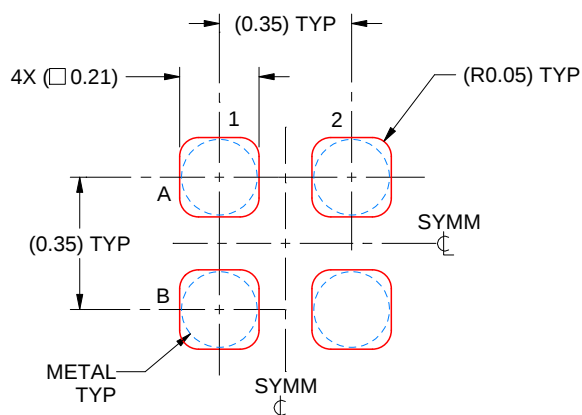
- Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. See Texas Instruments Literature No. SNVA009 ([www.ti.com/lit/snva009](http://www.ti.com/lit/snva009)).

## EXAMPLE STENCIL DESIGN

YCH0004

DSBGA - 0.4 mm max height

DIE SIZE BALL GRID ARRAY



SOLDER PASTE EXAMPLE  
BASED ON 0.075 mm THICK STENCIL  
SCALE: 50X

4224061/A 12/2017

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

## 重要声明和免责声明

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